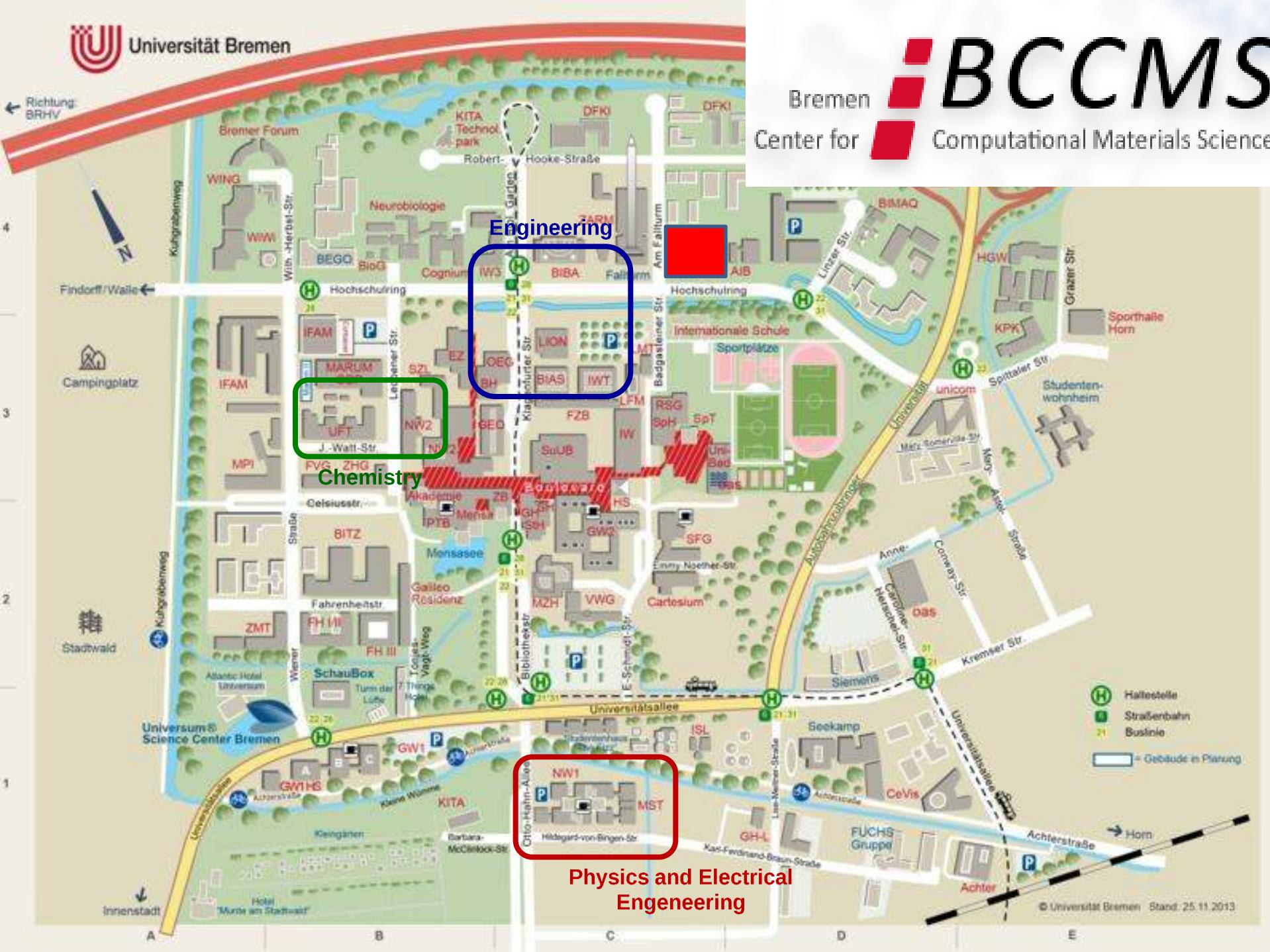


Bremen Center for Computational Materials Science





Bremen Center for Computational Materials Science

<http://www.bccms.uni-bremen.de/>

Founding Chair - 2006 Computational Materials Science

Thomas
Frauenheim



Vasily Ploshikhin

Airbus Endowed Chair – 2009/2010 Integrative Materials and Process Simulation & Engineering



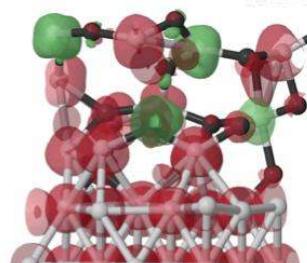
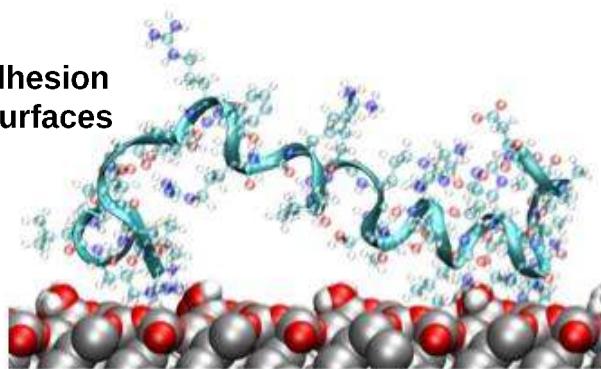
Tim Wehling

Electronic Structure and Correlated Nanosystems – ECN 2012

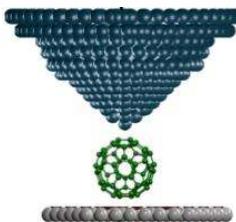
Bremen Center for Computational Materials Science

<http://www.bccms.uni-bremen.de>

Collagen adhesion
on silicon surfaces



Oxidation of Co-alloys

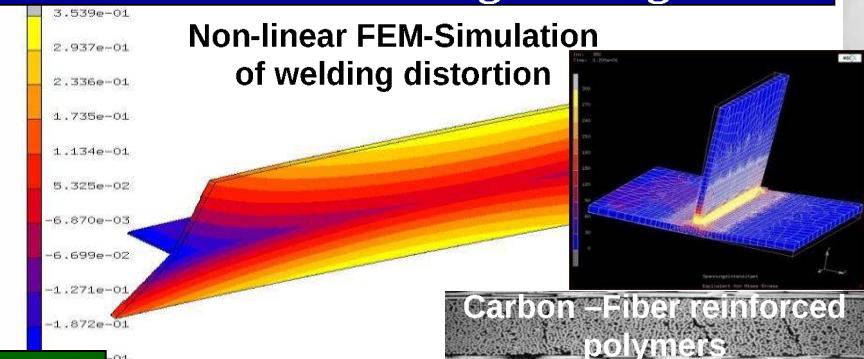


Chemical reactive
processes

Computational Materials Science

Integrative Materials and Process Simulation & Engineering

Non-linear FEM-Simulation
of welding distortion

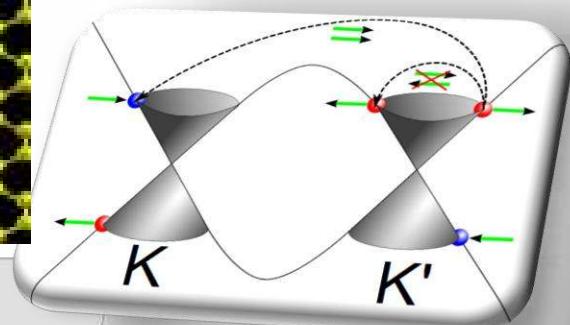


Carbon -Fiber reinforced
polymers



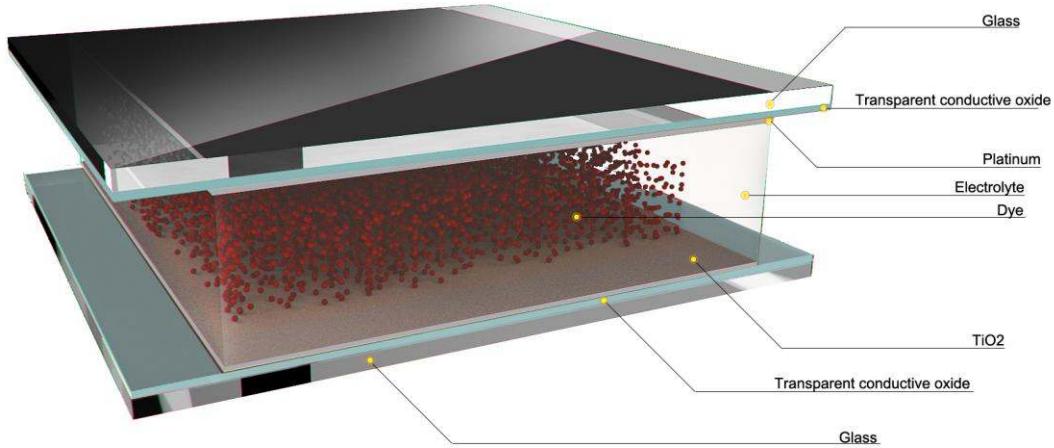
Physics of Graphene and novel
layered materials/devices

ES & Correlated Nanosystems

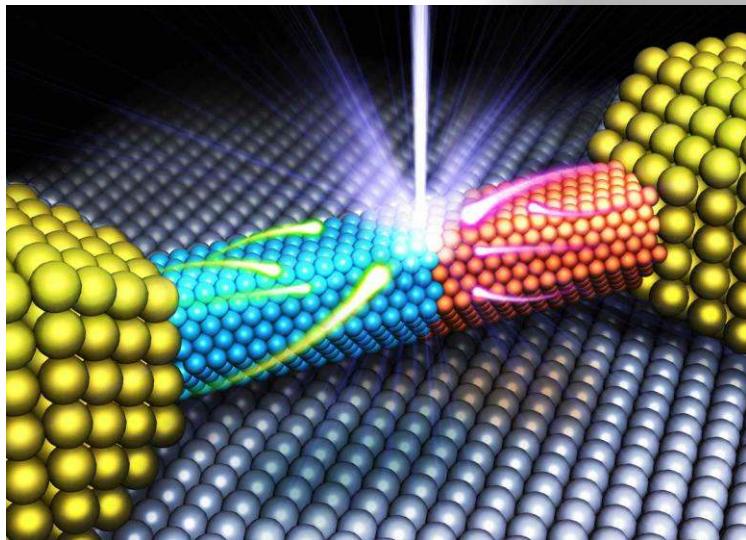


Atomistic modeling of quantum processes in nanoscale devices

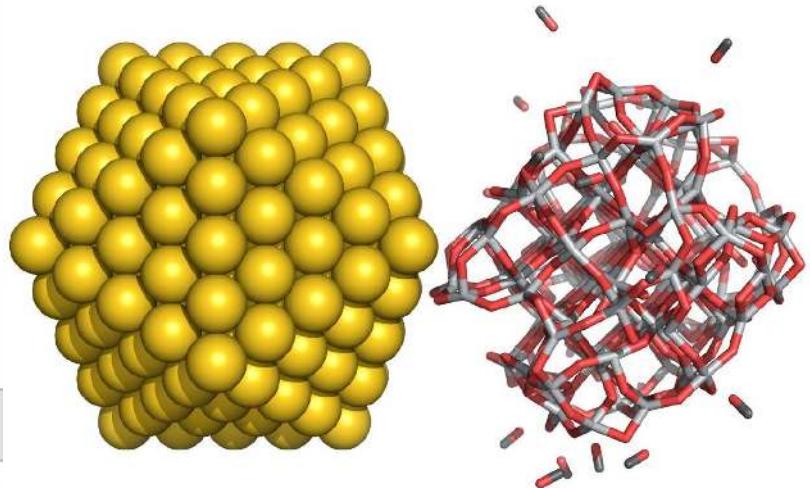
Photovoltaic devices



NW-LED



Hot electron injection



Solution of the many-body Schrödinger equation

$$\hat{H}\Psi(r_1, r_2, \dots, r_N) = E\Psi(r_1, r_2, \dots, r_N)$$

$$H_0 = T_e + V_{e-K}(\underline{\mathbf{r}}, \underline{\mathbf{R}}) + V_{e-e}(\underline{\mathbf{r}}) + V_{K-K}(\underline{\mathbf{R}})$$

$$T_e = \sum_{i=1}^{N_e} \frac{\mathbf{p}_i^2}{2m} \quad V_{e-e} = \sum_{i < j} v_{e-e}(\mathbf{r}_i - \mathbf{r}_j) \quad v_{e-e}(\mathbf{r} - \mathbf{r}') = \frac{e^2}{|\mathbf{r} - \mathbf{r}'|}$$

Very challenging and expensive to solve directly though not impossible (for small systems)

Variational / diffusion Quantum Monte Carlo
Post-Hartree-Fock Quantum Chemistry

Density-Functional-Theory: DFT

For $|GS\rangle$ use density $n(r)$ instead of $\Psi(r_1, r_2, \dots, r_N)$

$$E[\rho(\mathbf{r})] = \sum_{i=1}^N \int \psi_i(\mathbf{r}) \left(-\frac{\nabla^2}{2} \right) \psi_i(\mathbf{r}) d\mathbf{r} + \frac{1}{2} \iint \frac{\rho(\mathbf{r}_1)\rho(\mathbf{r}_2)}{|\mathbf{r}_1 - \mathbf{r}_2|} d\mathbf{r}_1 d\mathbf{r}_2 + E_{XC}[\rho(\mathbf{r})]$$

$$- \sum_{A=1}^M \int \frac{Z_A}{|\mathbf{r} - \mathbf{R}_A|} \rho(\mathbf{r}) d\mathbf{r}$$

$$E_H[\rho(\mathbf{r})] = \frac{1}{2} \iint \frac{\rho(\mathbf{r}_1)\rho(\mathbf{r}_2)}{|\mathbf{r}_1 - \mathbf{r}_2|} d\mathbf{r}_1 d\mathbf{r}_2$$

$$\rho(\mathbf{r}) = \sum_{i=1}^N |\psi_i(\mathbf{r})|^2$$

$$E_{XC}[\rho(\mathbf{r})] = \int \rho(\mathbf{r}) \varepsilon_{XC}(\rho(\mathbf{r})) d\mathbf{r}$$

Kohn-Sham equation

Includes all many-body effects

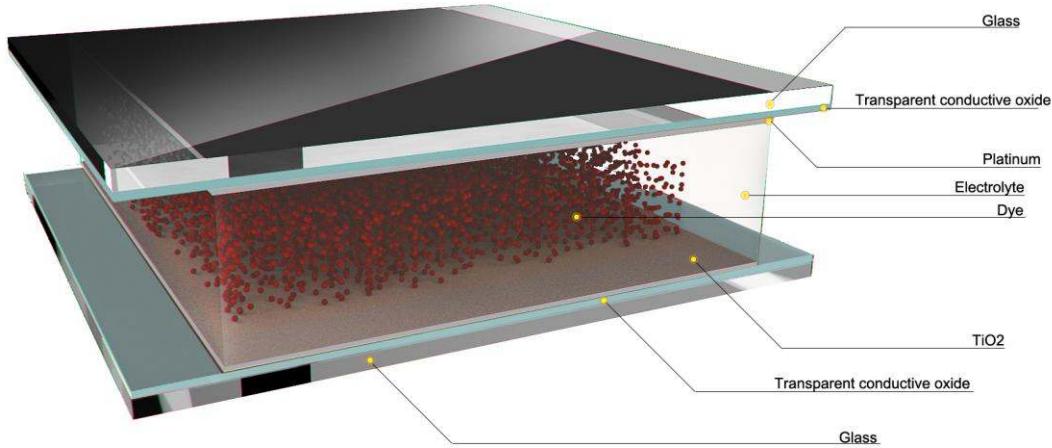
$$\left\{ -\frac{\nabla_1^2}{2} - \left(\sum_{A=1}^M \frac{Z_A}{r_{1A}} \right) + \int \frac{\rho(\mathbf{r}_2)}{r_{12}} d\mathbf{r}_2 + V_{XC}[\mathbf{r}_1] \right\} \psi_i(\mathbf{r}_1) = \varepsilon_i \psi_i(\mathbf{r}_1)$$

$$V_{XC}[\mathbf{r}] = \left(\frac{\delta E_{XC}[\rho(\mathbf{r})]}{\delta \rho(\mathbf{r})} \right)$$

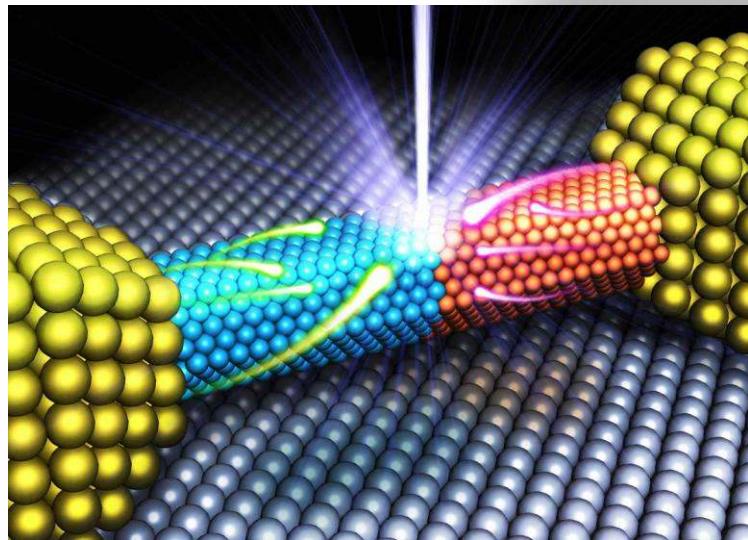
Today can be solved self-consistently for several 100 atoms

Atomistic modeling of quantum processes in nanoscale devices

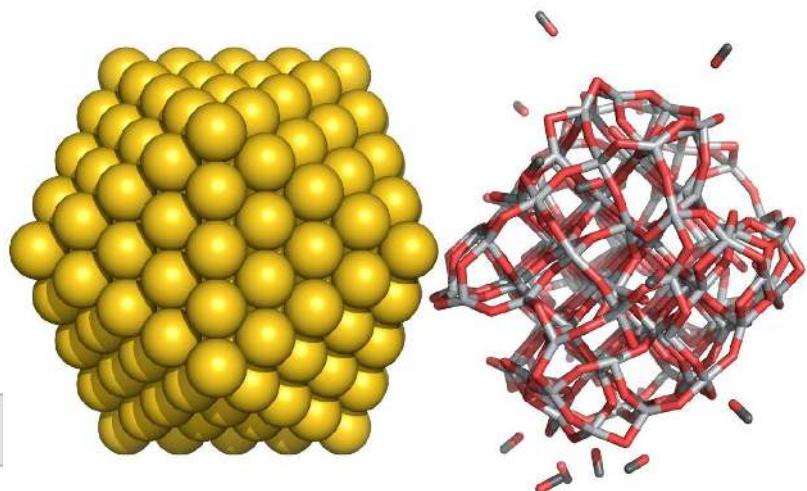
Photovoltaic devices



NW-LED

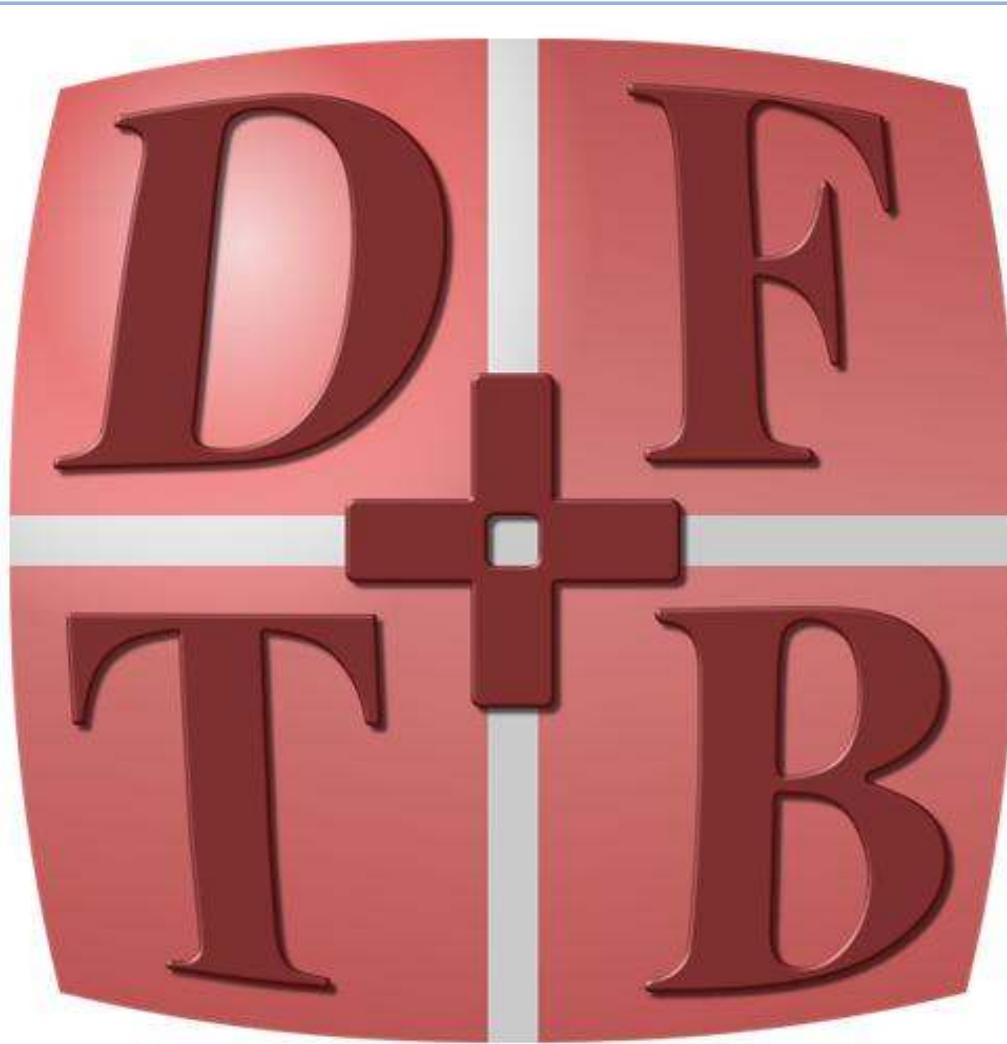


Hot electron injection

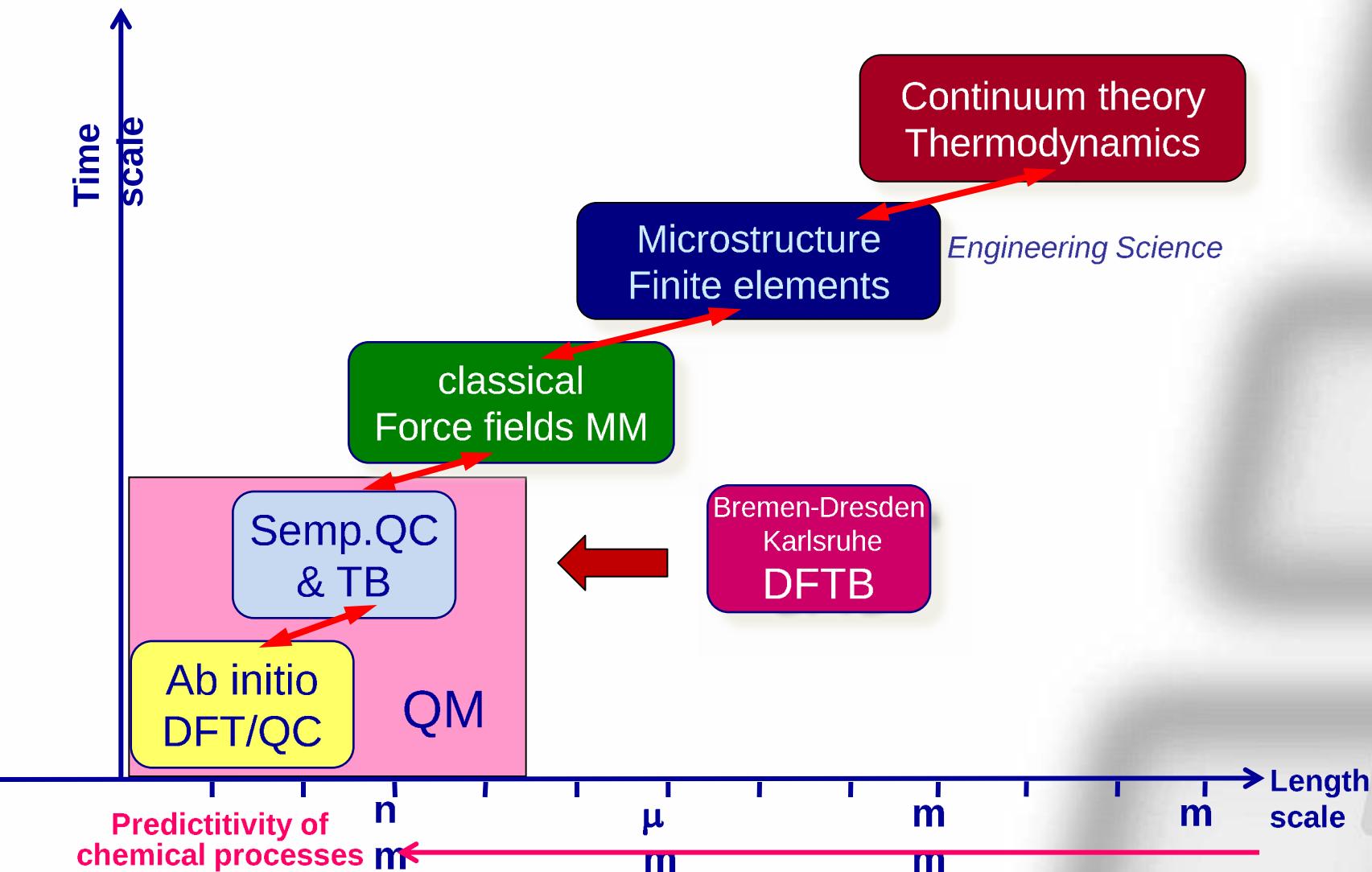


We need to go beyond
10.000 atom simulations

Atomistic modeling of photo-induced processes and energy conversion in nanoscale devices



Multi-scale hierarchy in materials simulations



From the LCAO-X _{α} -method to a modern DFTB-scheme



AN APPROXIMATION VARIANT OF LCAO-X-ALPHA METHODS

By: SEIFERT, G; ESCHRIG, H; BIEGER, W

ZEITSCHRIFT FUR PHYSIKALISCHE CHEMIE-LEIPZIG Volume: 267 Issue: 3 Pages: 529-539 Published: 1986

Construction of tight-binding-like potentials on the basis of density-functional theory: Application to carbon

D. Porezag,* Th. Frauenheim, and Th. Köhler

Technische Universität, Institut für Physik, Theoretische Physik III, D-09009 Chemnitz, Germany

G. Seifert and R. Kaschner

Technische Universität Dresden, Institut für Theoretische Physik, Mommsenstrasse

(Received 2 November 1994)

We present a density-functional-based scheme for determining the necessary nonorthogonal tight-binding (TB) models within the framework of the atomic-orbitals formalism using the local-density approximation (LDA). By center integrals the Hamiltonian and overlap matrix elements are calculated from densities and potentials rather than fitted to experimental data. We can determine the C-C, C-H, and H-H Hamiltonian and overlap matrix elements. The exchange potential appearing in most TB models is fitted to self-consistent calculations within the LDA. The calculation of forces is easy and allows an application of the method to molecular dynamics simulations. Despite its extreme simplicity, the method is transferable to various systems, such as fullerenes and hydrocarbon systems. The determination of equilibrium geometries, total energy minimization, and vibrational modes of carbon clusters, hydrocarbon molecules, and solid-state models yield results showing an overall good agreement with more sophisticated methods.



sired matrix elements. For that reason, we will refer to our method as a nonorthogonal DF-based TB scheme.

Self-consistent-charge density-functional tight-binding method for simulations of complex materials properties

M. Elstner

*Universität-GH, Paderborn, Fachbereich Physik, Theoretische Physik, D-33098 Paderborn, Germany
and Department of Molecular Biophysics, German Cancer Research Center, D-69120 Heidelberg, Germany*

D. Porezag, G. Jungnickel, J. Elsner, M. Haugk, and Th. Frauenheim

Universität-GH, Paderborn, Fachbereich Physik, Theoretische Physik, D-33098 Paderborn, Germany

S. Suhai

Department of Molecular Biophysics, German Cancer Research Center, D-69120 Heidelberg, Germany

G. Seifert

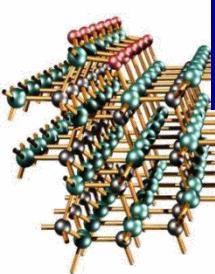
*Institut für Theoretische Physik, Mommsenstrasse 13, D-01062 Dresden, Germany
(19 September 1997; revised manuscript received 19 March 1998)*

UPB Dr. habil 2003



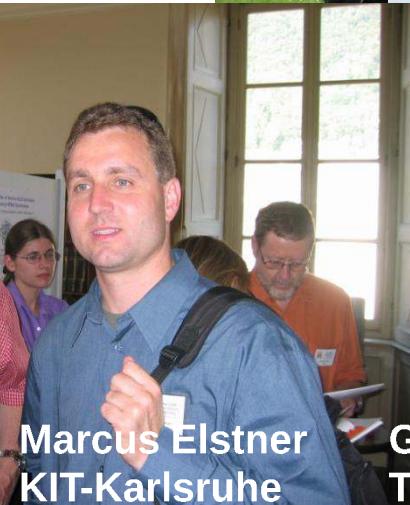
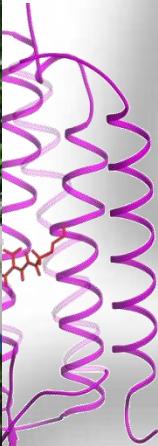
DFTB: 2562 citations

DFTB-method



Theory of complex materials @ UPB

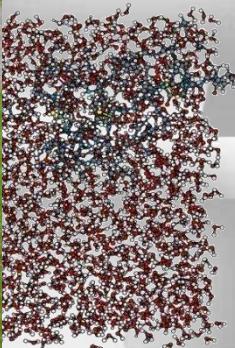
supported by DFG, DAAD, VW, EC, BMBF, FhG, Humboldt



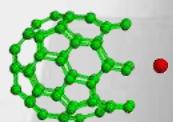
Marcus Elstner
KIT-Karlsruhe

Gotthard Seifert
TU Dresden

Collaborative effort



Theory of complex materials



Outline of the Talk

- 1. Brief introduction of the DFTB-method**
- 2. Examples for device modeling**
- 3. Ways to improve ground state accuracy and efficiency**
- 4. TD-DFTB properties in linear response**
- 5. NO-reduction on TiO_2 surfaces**
- 6. Charge transfer excitations using pp-DFTB**
- 7. Non-adiabatic Ehrenfest molecular dynamics**

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DFTB relies on Density-Functional-Theory

For $|GS\rangle$ use density $n(r)$ instead of $\Psi(r_1, r_2, \dots, r_N)$

$$E[\rho(\mathbf{r})] = \sum_{i=1}^N \int \psi_i(\mathbf{r}) \left(-\frac{\nabla^2}{2} \right) \psi_i(\mathbf{r}) d\mathbf{r} + \frac{1}{2} \iint \frac{\rho(\mathbf{r}_1)\rho(\mathbf{r}_2)}{|\mathbf{r}_1 - \mathbf{r}_2|} d\mathbf{r}_1 d\mathbf{r}_2 + E_{XC}[\rho(\mathbf{r})]$$

$$- \sum_{A=1}^M \int \frac{Z_A}{|\mathbf{r} - \mathbf{R}_A|} \rho(\mathbf{r}) d\mathbf{r}$$

$$E_H[\rho(\mathbf{r})] = \frac{1}{2} \iint \frac{\rho(\mathbf{r}_1)\rho(\mathbf{r}_2)}{|\mathbf{r}_1 - \mathbf{r}_2|} d\mathbf{r}_1 d\mathbf{r}_2$$

$$\rho(\mathbf{r}) = \sum_{i=1}^N |\psi_i(\mathbf{r})|^2$$

$$E_{XC}[\rho(\mathbf{r})] = \int \rho(\mathbf{r}) \varepsilon_{XC}(\rho(\mathbf{r})) d\mathbf{r}$$

Kohn-Sham equation

Includes all many-body effects

$$\left\{ -\frac{\nabla_1^2}{2} - \left(\sum_{A=1}^M \frac{Z_A}{r_{1A}} \right) + \int \frac{\rho(\mathbf{r}_2)}{r_{12}} d\mathbf{r}_2 + V_{XC}[\mathbf{r}_1] \right\} \psi_i(\mathbf{r}_1) = \varepsilon_i \psi_i(\mathbf{r}_1)$$

$$V_{XC}[\mathbf{r}] = \left(\frac{\delta E_{XC}[\rho(\mathbf{r})]}{\delta \rho(\mathbf{r})} \right)$$

Today can be solved self-consistently for several 100 atoms

Major approximations in DFTB compared to DFT

- Expansion of KSh-energy in 2nd or more recently 3rd order density fluctuation
- Reference density as atomic superposition $n(\mathbf{r}) = n_0(\mathbf{r}) + \delta n(\mathbf{r})$ $n_0(\mathbf{r}) = \sum_{\alpha} n_0^{\alpha}(\mathbf{r} - \mathbf{R}_{\alpha})$
- Minimal basis representation of KSh-eigenstates $\psi_i = \sum_{\nu} c_{i\nu} \phi(\mathbf{r} - \mathbf{R}_{\alpha(\nu)})$
- Two-center integral approximation, fitting of repulsive interactions
- Self-consistency in atom-centered Mulliken charges in monopole approximation

$$H_{\mu\nu}^{\text{bs}} = \langle \phi_{\nu} | \hat{T} + V_{\text{eff}} [n_0^{\alpha} + n_0^{\beta}] | \phi_{\nu} \rangle \quad S_{\mu\nu} = \langle \phi_{\mu} | \phi_{\nu} \rangle$$

$$H_{\mu\mu}^{\text{bs}} = \varepsilon_{\mu}^{\text{free atom}}$$

$$E_{\text{rep}}^{\alpha\beta}(R_{\alpha\beta}) = E_{\text{ab initio}}(R_{\alpha\beta}) - [E_{\text{bs}} + E_2](R_{\alpha\beta})$$

What We NEED

- H and S matrix versus distance for each At-type, At-type pair (s/p/d – 10 SK-tables)
- Automated tools will be made available – NEW SK-data format

dftb.org the DFTB website

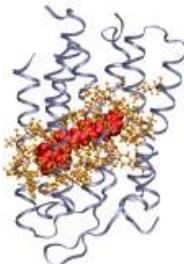
- Home
- About DFTB
- Codes
- Parameters
- Events
- Sitemap

Username:

Password:

Login

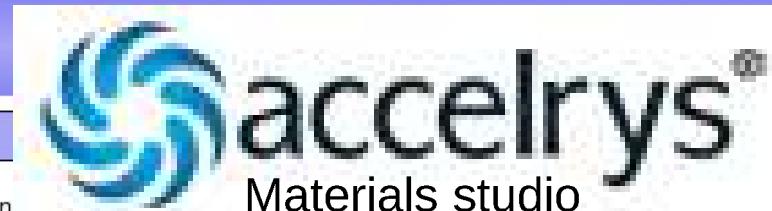
Welcome to DFTB!



This site contains some information about the Density Functional Theory (DFT) method. If you want to know more about this fast and efficient quantum mechanical method, please have a look at the [short description](#) about DFTB and eventually [some references](#).

The DFTB method has several implementations. For a (non-exhaustive) list of them, please have a look at the [implementations subpage](#).

If you are looking for parameters (Slater-Koster files), you can have a look at the [parameter subpage](#). There are also parameter sets available for Gaussian and DFTB/Gaussian (soon).



**Many other worldwide distributed codes:
ADF, ATK, DeMon, CHARMM,
Gaussian,**

Three Slater-Koster sets available

2006-11-30

There are three Slater-Koster parameter sets ([mio-0-1](#), [pbc-0-1](#), [hyb-0-1](#)) available for [download](#). They are provided by the groups of **Prof. Frauenheim (BCCMS, Uni Bremen)** and **Prof. Elstner (Theoretical Chemistry, TU Braunschweig)**. With the help of these sets, the DFTB method can be applied to a broad range of systems, including organic and inorganic molecules, solid semiconductors and semiconductor surfaces and hybrid organic/inorganic systems.

DFTB+ on www.dftb-plus.info

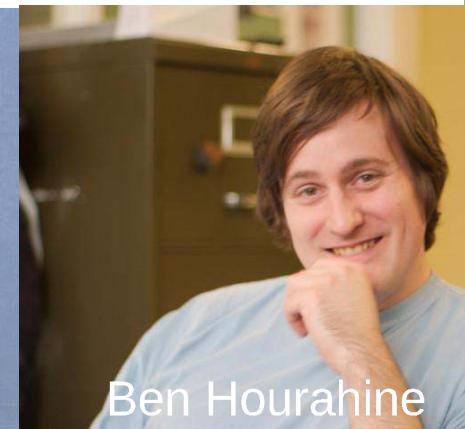
The [dftb.org](#) site is being redesigned now. It should become a general site for distributing Slater-Koster parametrisation files for the method. Information about the new site will be available on www.dftb-plus.info from now on.

DFTB at the ACS Fall Meeting in San Francisco (presentations)

The DFTB symposium at the ACS Fall Meeting in San Francisco was a real success. All the presentations were recorded and abstracts and some of the presentations are [available on our website](#) now.



Balint Aradi



Ben Hourahine

**DFTB+ since 2007 distributed as open source code
about 3000 downloads**



MM
M. Elstner, Q. Cui, M. Karplus

TB+ (Implemented/pending)

NEGreen-DFTB

Charge transfer

A. DiCarlo, A. P.



Linear scaling

W. Yang

CPMD

T. Heine



GW/BSE-DFTB

T. Niehaus

LDA+U/SO

non-collin. magnetism

B. Hourahine



inter.

DFTB+



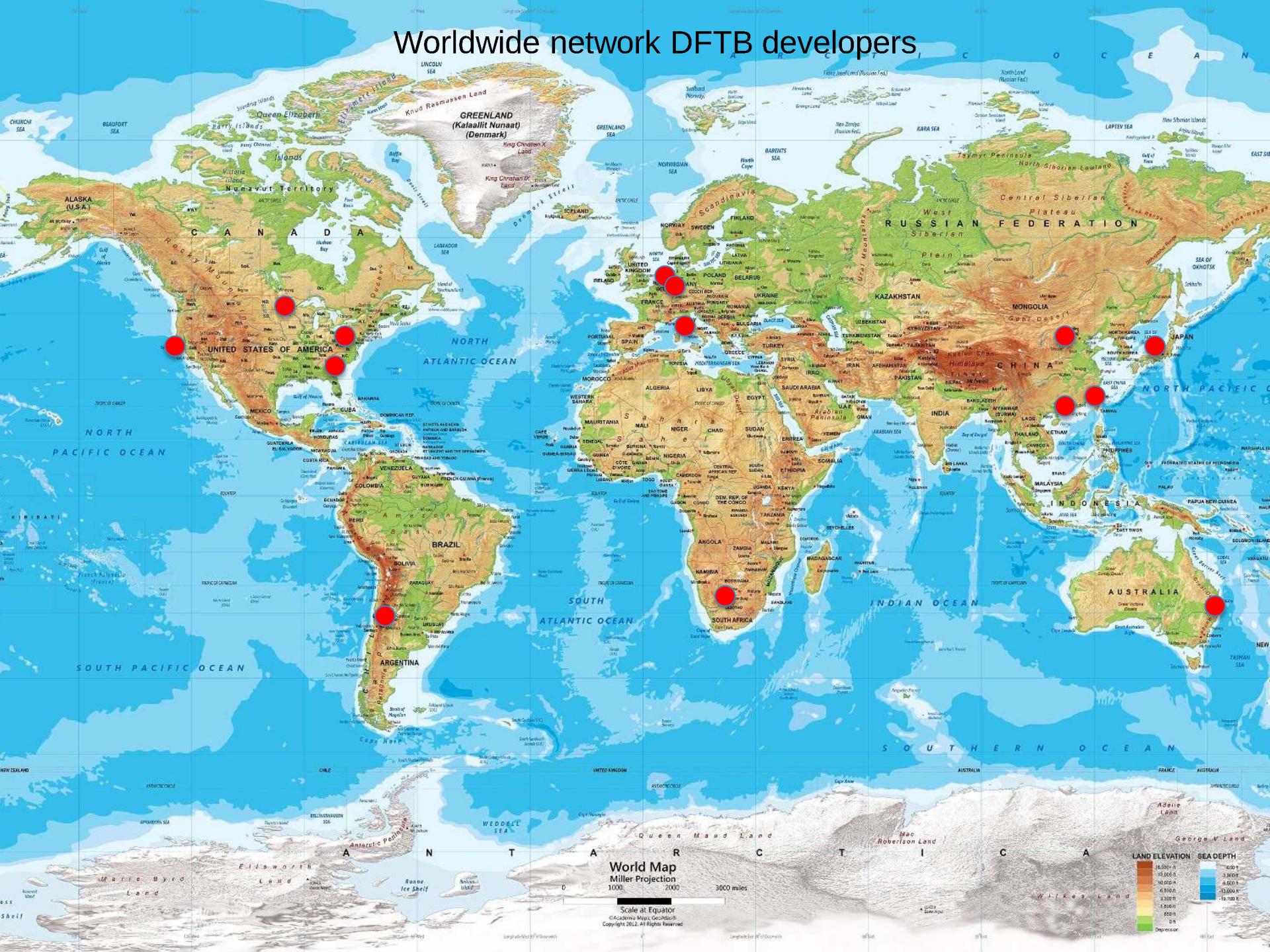
Since June: LGPL licenced open source DFTB+ release 17.1

We think its now time to go even further! The aim is to extend the active community and to make DFTB+ useful for an even broader scientific community in future years. Therefore, we have changed the license of the software to the open source license LGPL, enabling you to

- * obtain and use DFTB+ without any registration process, independent of whether your research is commercial or not,
- * interface and distribute DFTB+ as part of your academic or commercial software package,
- * easily contribute to DFTB+ by using our publicly hosted repository.

For more details see <http://www.dftbplus.org>

Worldwide network DFTB developers



DFTB Developer Meeting, October 2015

Next generation approximate DFTB method





WELCOME

INVITED SPEAKERS

ORGANIZERS

WORKSHOP PROGRAM

VENUE&ROUTE

ACCOMODATION

VISA INFORMATION

CONTACT INFORMATION

REGISTRATION

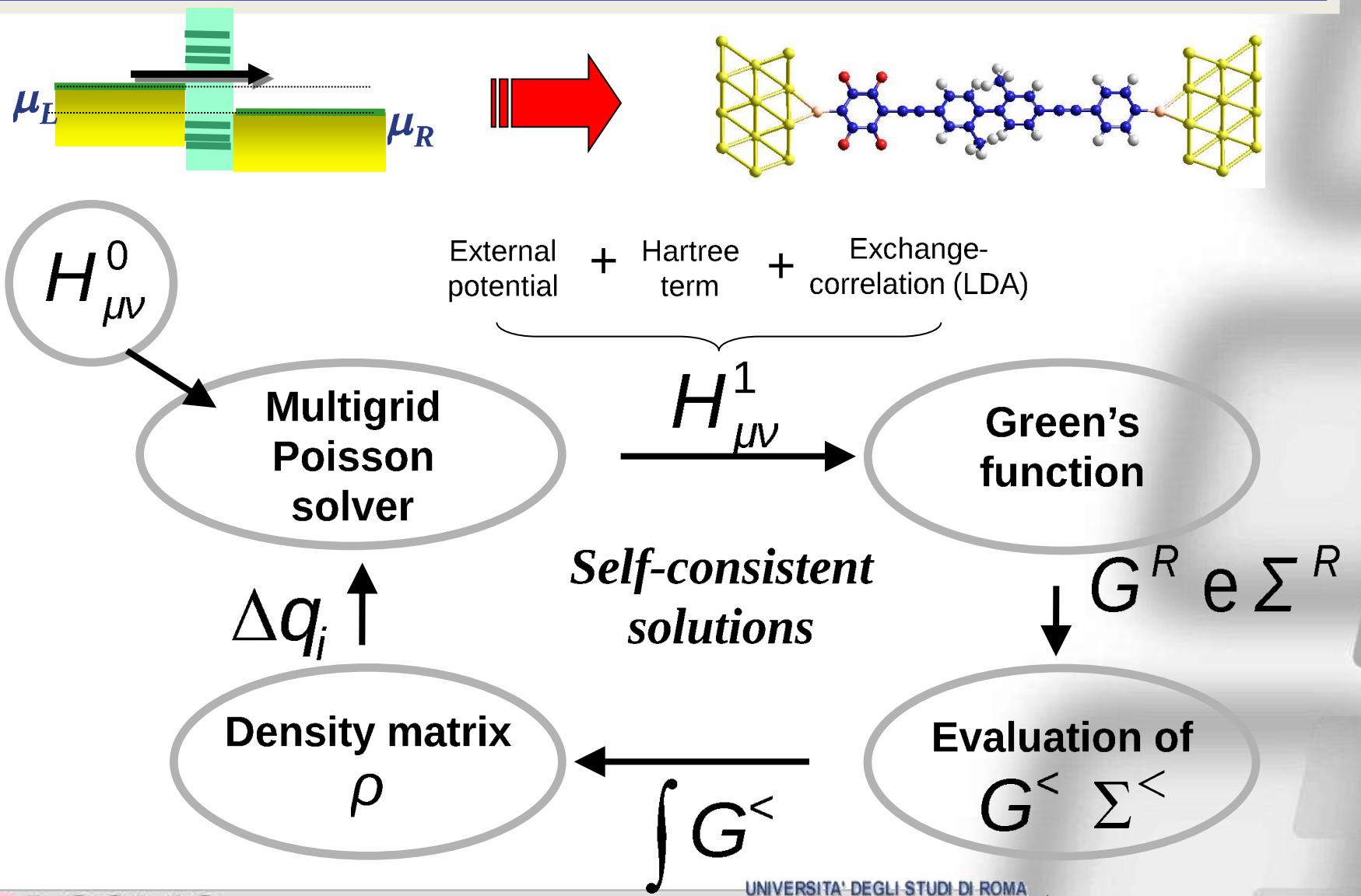
International CECAM-Workshop on approximate quantum methods in the ab initio world

Objective : The primary goal of the proposed CECAM workshop is to facilitate communication and collaboration between users and developers of multi-scale quantum methods, with emphasis on approximate DFT and semi-empirical (SE) methods, linear-scaling quantum mechanical and hybrid quantum mechanical/molecular mechanics approaches. The meeting is intended to provide a unique forum to bring together world leaders of different communities in method development to discuss recent advances in current methodologies, to assess their similarities, and to identify critical challenges in the field as well as future directions for research and development of the next generation of computational tools. On the more technical side, this will include the discussion of the state of the art in efficient parameterization techniques, reference databases, and multi-objective optimization. Simultaneously, the workshop will involve people from the DFT and ab initio communities, who are interested in SE/DFTB methods as a supplement to their first principles codes, for example to use the more approximate quantum techniques for screening large numbers of structures in high-dimensional configuration space and for exploring extended trajectories under real environmental conditions (e.g. deMon2k, ATK, ADF, SIESTA).

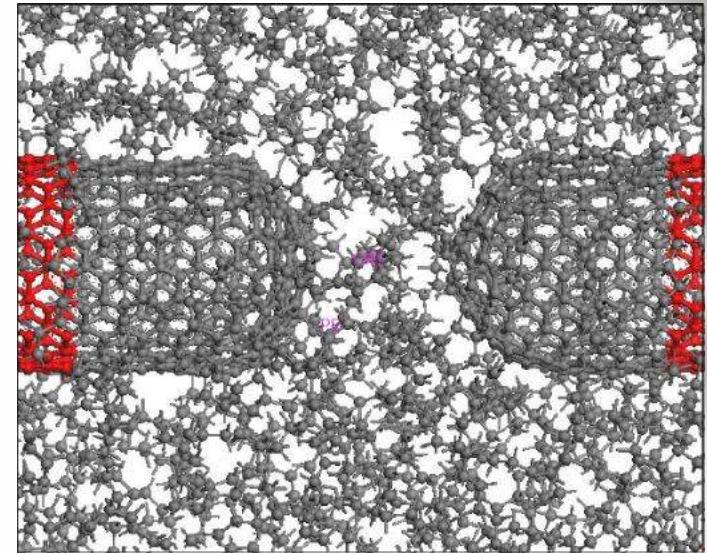
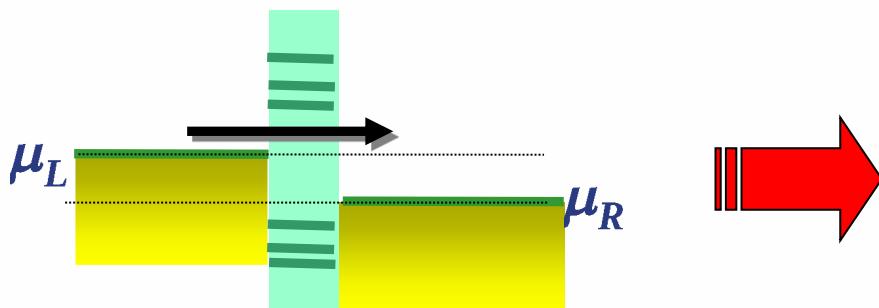
Multi-Scale Quantum Mechanical Analysis of Condensed Phase Systems: Methods and Applications



NEGF quantum transport under open boundary conditions



Single molecule quantum transport

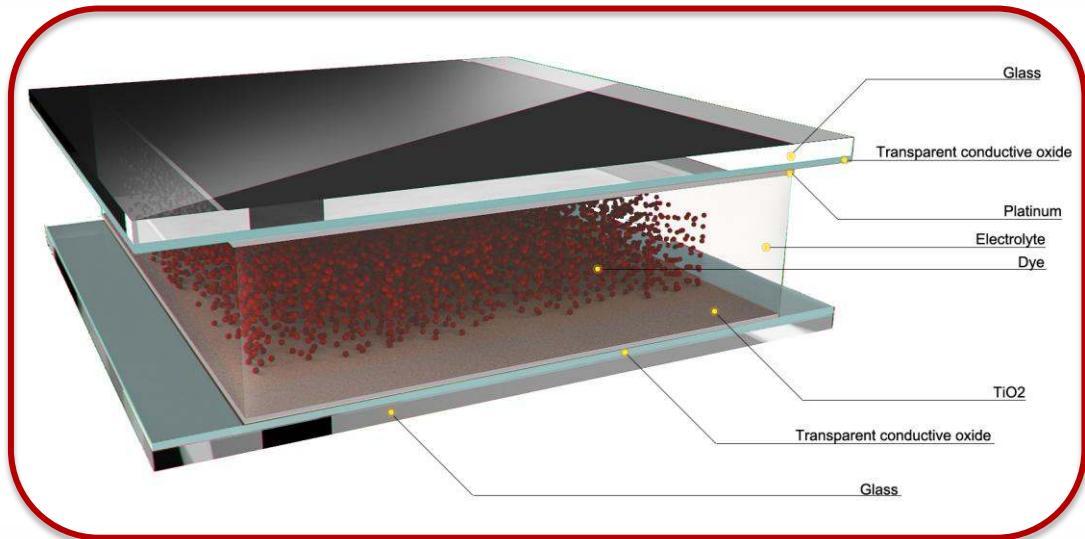


$$I = \frac{2e}{h} \int_{\mu_R}^{\mu_L} Tr[\Sigma^<G^> - \Sigma^>G^<]dE$$

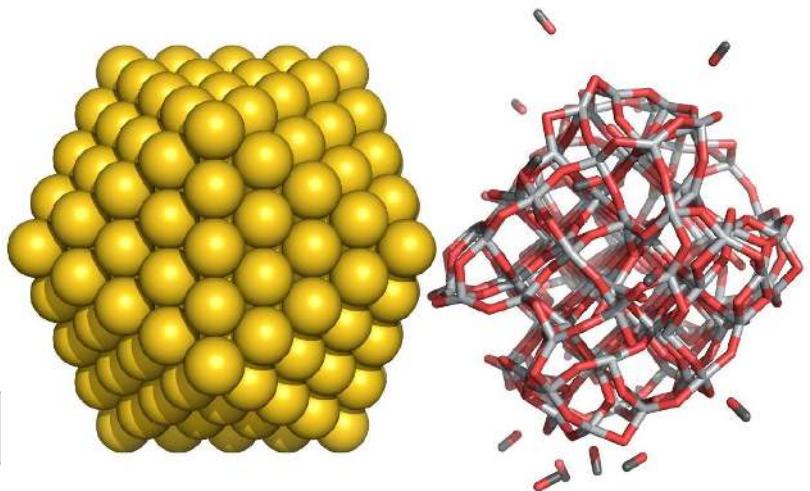
Meir & Wingreen, Phys. Rev. Lett. (1992)

Atomistic modeling of quantum processes in nanoscale devices

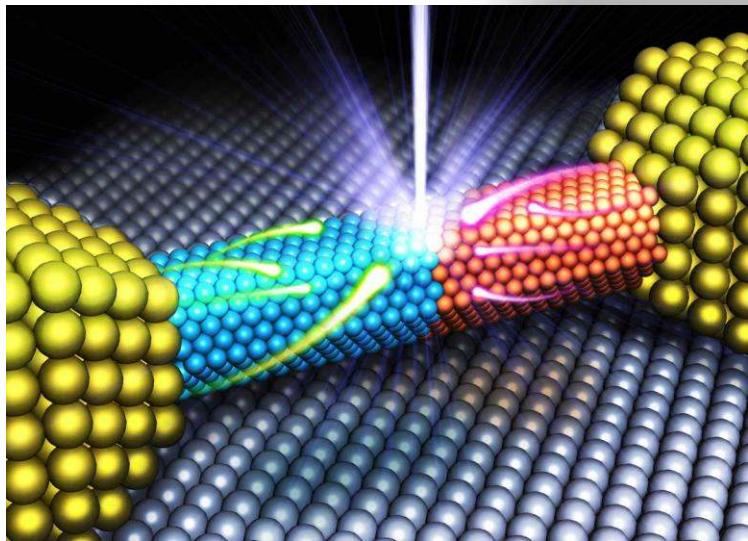
Photovoltaic devices



Hot electron injection



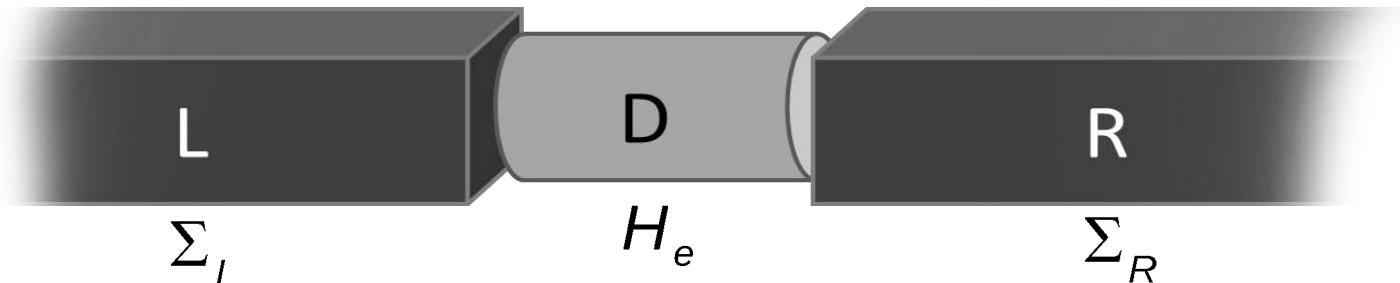
NW-LED



Electron – photon interaction

Electron-Photon Interactions

SiNW-SC PN-junction, linearly polarized light applied:



Hamiltonian in Coulomb Gauge:

$$H = \frac{1}{2m}(\vec{p} + e\vec{A})^2 + V(\vec{r}) \equiv H_e + \frac{e}{m}\vec{A} \cdot \vec{p} + \frac{e^2}{2m}\vec{A}^2$$

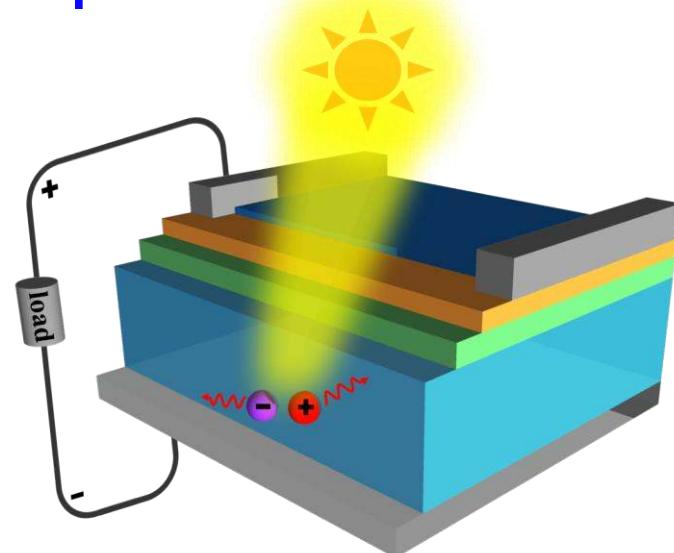
In dipole approximation - vector potential in **second quantization**:

$$\vec{A} = \vec{a} \left(\frac{\hbar\sqrt{\tilde{\mu}\tilde{\epsilon}}}{2N\omega\epsilon c} F_r \right)^{1/2} \left(b e^{-i\omega t} + b^\dagger e^{i\omega t} \right)$$

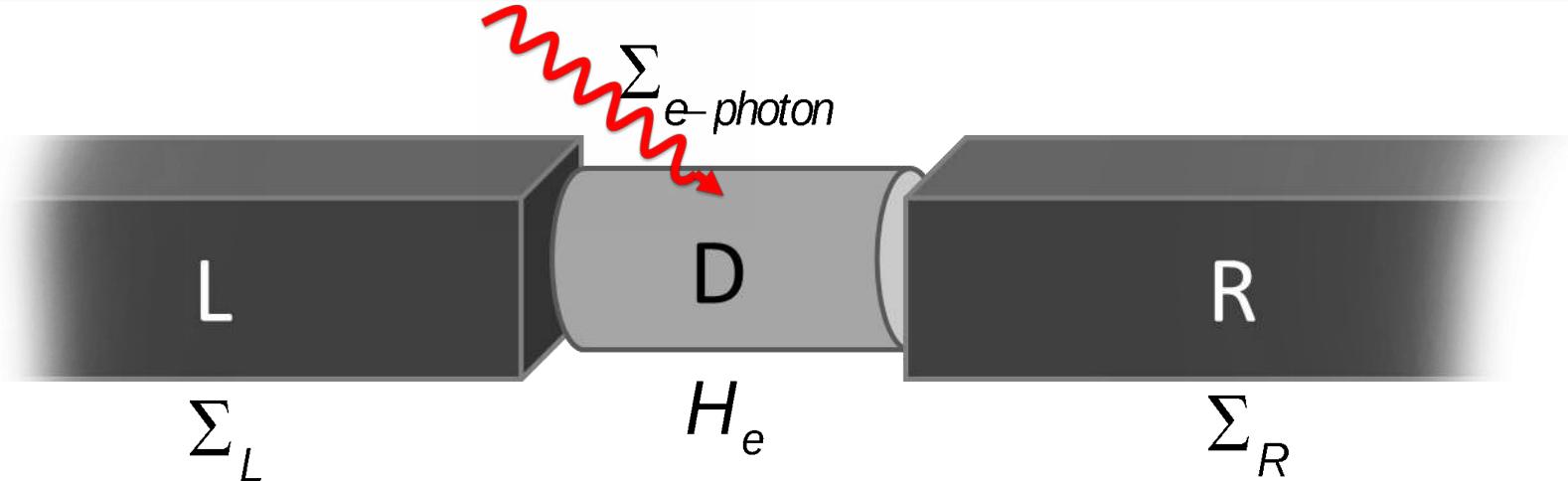
interaction Hamiltonian in atomic basis

$$H_{ep} = \sum_{\mu\nu} \frac{e}{m} \langle \mu | \vec{A} \cdot \vec{p} | \nu \rangle d_\mu^* d_\nu = \sum_{\mu\nu} M_{\mu\nu} (b e^{-i\omega t} + b^* e^{i\omega t}) d_\mu^* d_\nu$$

very similar to electron-phonon interaction



Electron-Photon Interactions



$$\Sigma_{ep}(\tau, \tau') = iM[D(\tau, \tau')G(\tau, \tau')]M$$

Photon Green's Function: $D^>(t, t') = [N e^{i\omega(t-t')} + (N+1) e^{-i\omega(t-t')}]$

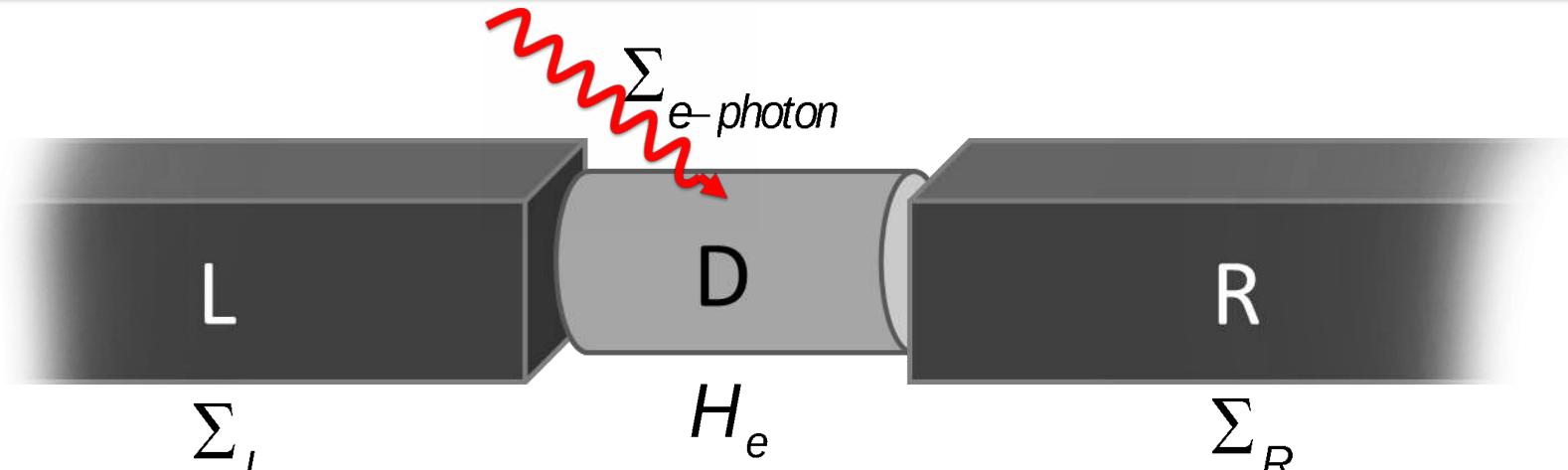
$$D^<(t, t') = [N e^{-i\omega(t-t')} + (N+1) e^{i\omega(t-t)}]$$

Fourier transform:

$$\Sigma_{ep}^{<,>}(E) = M \left[N G^{<,>}(\text{absorption}) (E \mp \hbar\omega) + (N+1) G^{<,>}(\text{emission}) (E \pm \hbar\omega) \right] M$$

Both Green's functions and self energies to be calculated self-consistently

Electron-Photon Interactions



Extra terms in self-energy

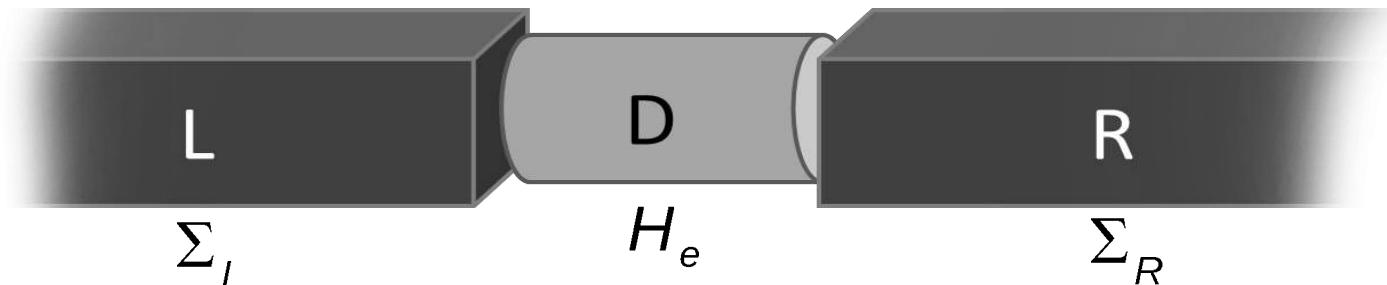
$$G^r(E) = [E\mathbf{S} - H - \Sigma_L^r(E) - \Sigma_R^r(E) - \Sigma_{ep}^r(E)]^{-1}$$

Current in NEGF:

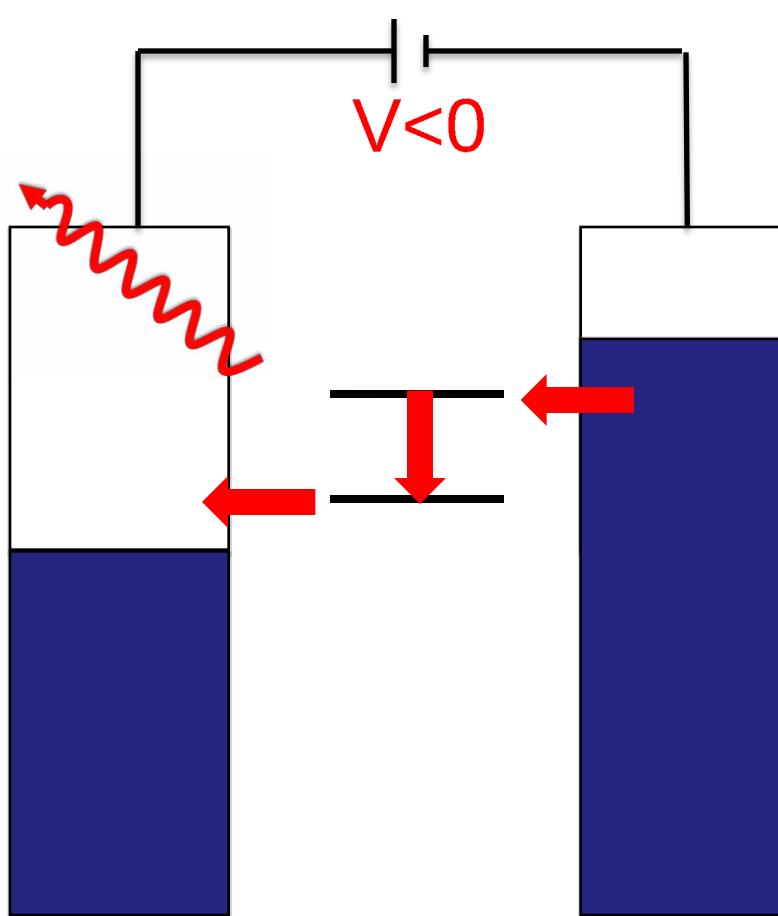
$$I_\alpha = \frac{2e}{\hbar} \int \frac{dE}{2\pi} \text{Tr} \left[\Sigma_\alpha^<(E) G^>(E) - \Sigma_\alpha^>(E) G^<(E) \right]$$

Current: $\begin{cases} \text{elastic part: } I_\alpha^{el} = \frac{2e}{\hbar} \int \frac{dE}{2\pi} (f_\alpha - f_\beta) \text{Tr} \left[\Gamma_\alpha(E) G^r(E) \Gamma_\beta(E) G^a(E) \right] \\ \text{inelastic part: } I_\alpha^{inel} = \frac{2e}{\hbar} \int \frac{dE}{2\pi} \text{Tr} [\Gamma_\alpha(E) G^r(E) \Gamma_{eff}(E) G^a(E)] \end{cases}$

Inelastic scatterings



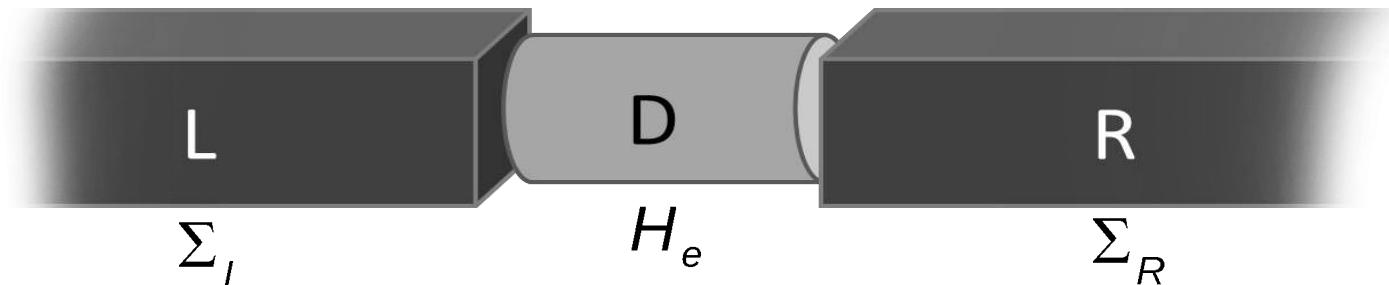
Light emission - LED



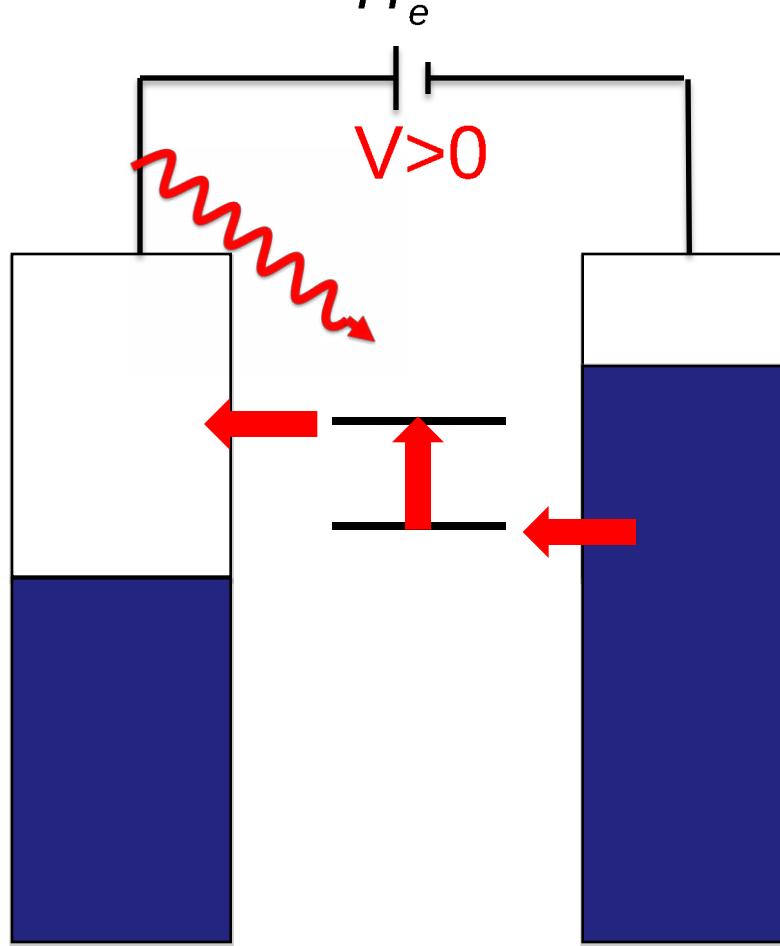
Due to applied bias
electrons enter from
right

Electron recombines
with a hole, while a
Photon emitted

Inelastic scatterings



Excitation by light
Solar Cell

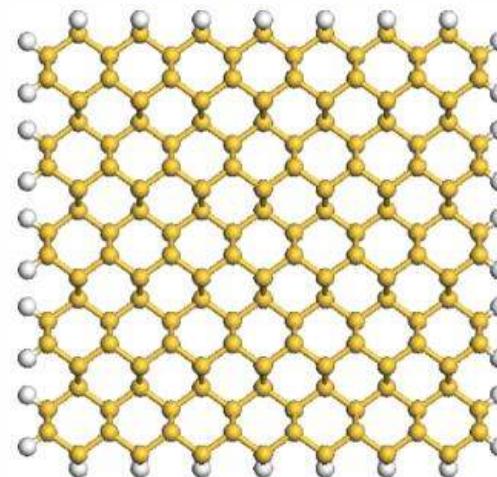
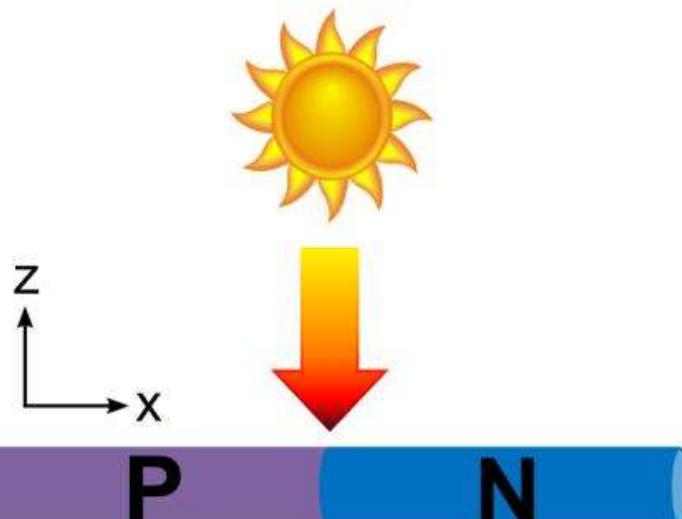


Electrons can absorb a photon leaving the device with higher energy

2 Si nanowire pn-junctions as photovoltaic device



SiNWs, [110] direction, 25 nm

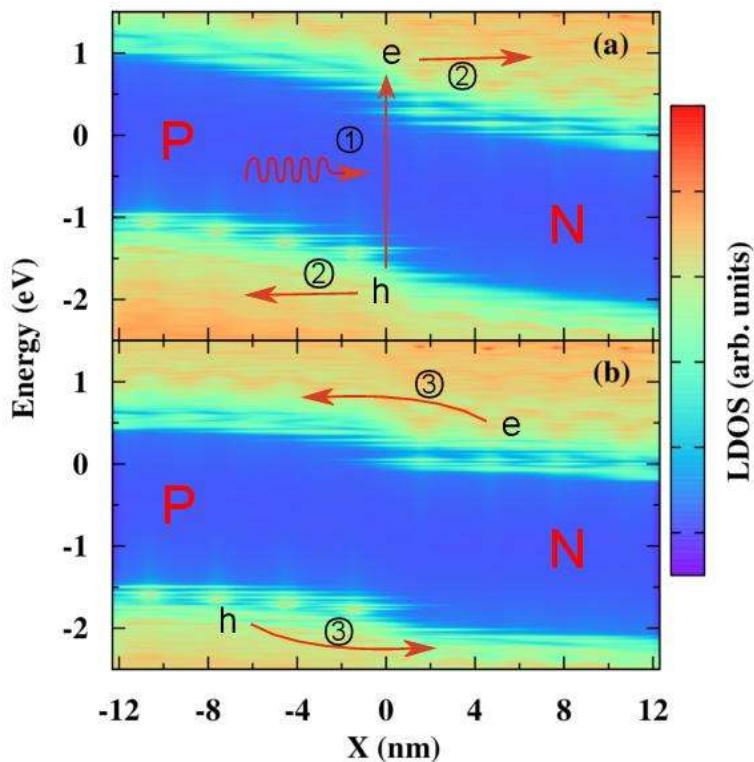


NW-A 6656 atoms; NW-B 12672 atoms

| | Cross-section | Length | Doping concentration |
|------|---------------|--------|---------------------------------------|
| NW-A | 2nm x 2nm | 25nm | $8.0 \times 10^{19} \text{ cm}^{-3}$ |
| NW-B | 3nm x 3nm | 25nm | $3.56 \times 10^{19} \text{ cm}^{-3}$ |

I-V characteristics, short circuit current, open circuit voltage, power conversion efficiency

Simulation of photovoltaic device



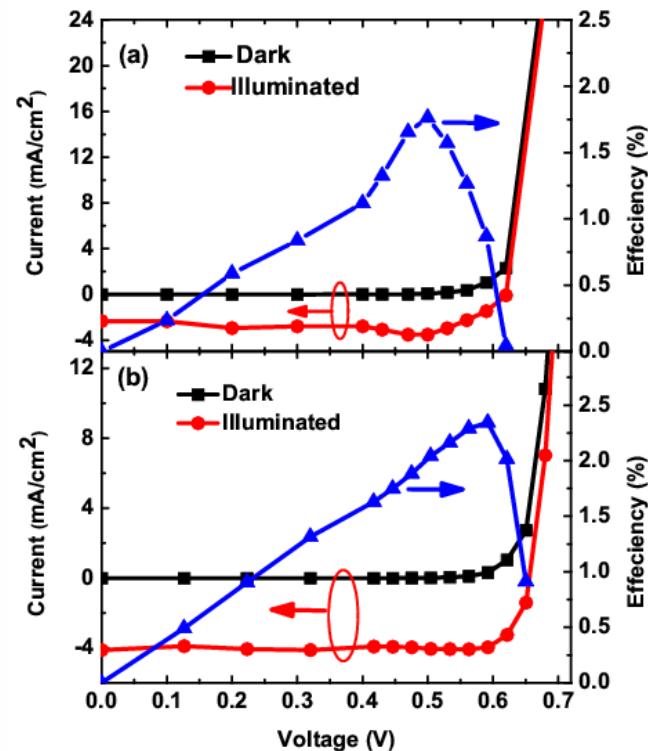
LDOS of the NW-A with forward bias a) 0V b)

0.6V

Ban-

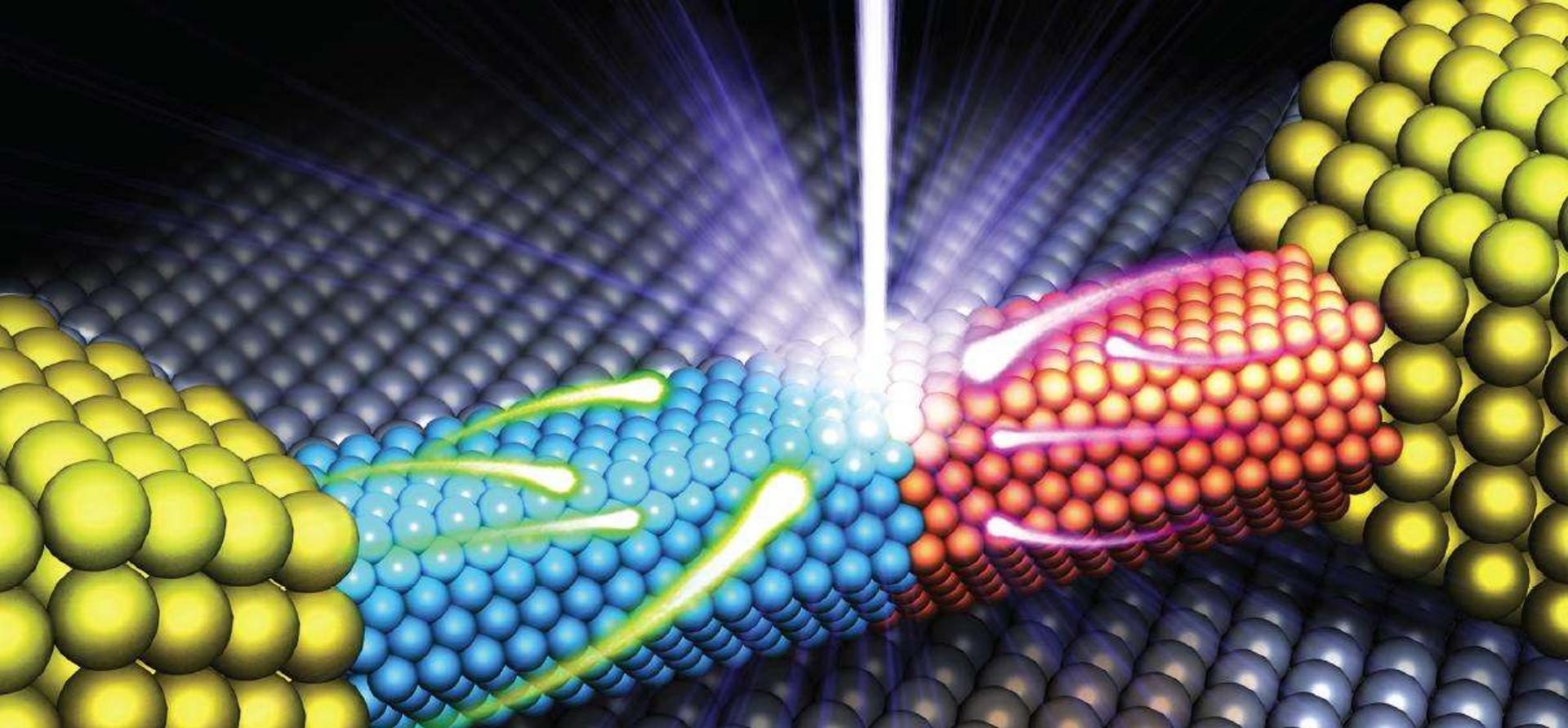
volt-

| | NW-A | NW-B |
|------------|-------------------------|-------------------------|
| I_{SC} | 2.33 mA/cm ² | 4.19 mA/cm ² |
| V_{OC} | 0.62 V | 0.66 V |
| α^* | 6.5% | 12.4% |



I-V curves of (a) NW-A and (b)
NW-B with and without light
illumination.

Photon energy is 2.5 eV
Enhancement by antireflection and
light-trapping techniques



COMMUNICATION

[View Article](#)
[View Journal](#)



Cite this: *Nanoscale*, 2016, **8**, 13168

Received 21st March 2016,
Accepted 20th May 2016

DOI: 10.1039/c6nr02356h

www.rsc.org/nanoscale

Quantum mechanical modeling the emission pattern and polarization of nanoscale light emitting diodes

Rulin Wang,^a Yu Zhang,^b Fuzhen Bi,^{a,c} Thomas Frauenheim,^d GuanHua Chen^e and ChiYung Yam^{*a,e}

Outline of the Talk

- 1. Brief introduction of the DFTB-method**
- 2. Examples for device modeling**
- 3. Ways to improve ground state accuracy and efficiency**
- 4. TD-DFTB properties in linear response**
- 5. NO-reduction on TiO_2 surfaces**
- 6. Charge transfer excitations using pp-DFTB**
- 7. Non-adiabatic Ehrenfest molecular dynamics**

Improvement of ground and excited state accuracy

SCC-DFTB2 - consistent strong underestimation of Hydrogen bonds

Wrong qualitative description of Singlet-Triplet Excitations in TD-DFTB

Ways to improve ground state accuracy

- 3-rd order DFTB (DFTB3)
 - Multipole interactions
 - Onsite correction
 - Many-body dispersion interactions (Tkatchenko et al. PRL 2012)
- 
- highly improved H-bonds

**All improvements are crucial for studies under environmental conditions,
e.g. solvents and in particular for macromolecular systems**

DFTB3

Qiang Cui (Madison) and Marcus Elstner



- Expansion of the total energy up to third order in $\delta n(\mathbf{r})$:

$$E_{\text{tot}} = E_{\text{bs}}[n_0] + E_{\text{rep}}[n_0] + E_2[n_0, \delta n^2] + E_3[n_0, \delta n^3]$$

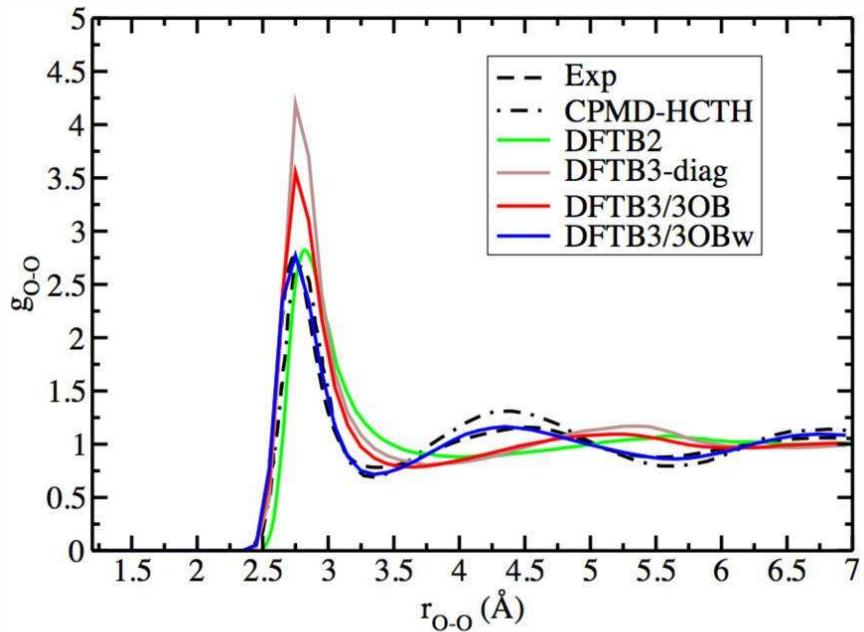
$$E_3 = \frac{1}{3} \sum_A \sum_B q_A^2 q_B \Gamma_{AB}$$

$$\Gamma_{AB} = \left. \frac{\partial \gamma_{AB}}{\partial U_A} \frac{\partial U_A}{\partial q_A} \right|_{q_A^0} \quad \Gamma_{AA} = \left. \frac{1}{2} \frac{\partial \gamma_{AA}}{\partial U_A} \frac{\partial U_A}{\partial q_A} \right|_{q_A^0}$$

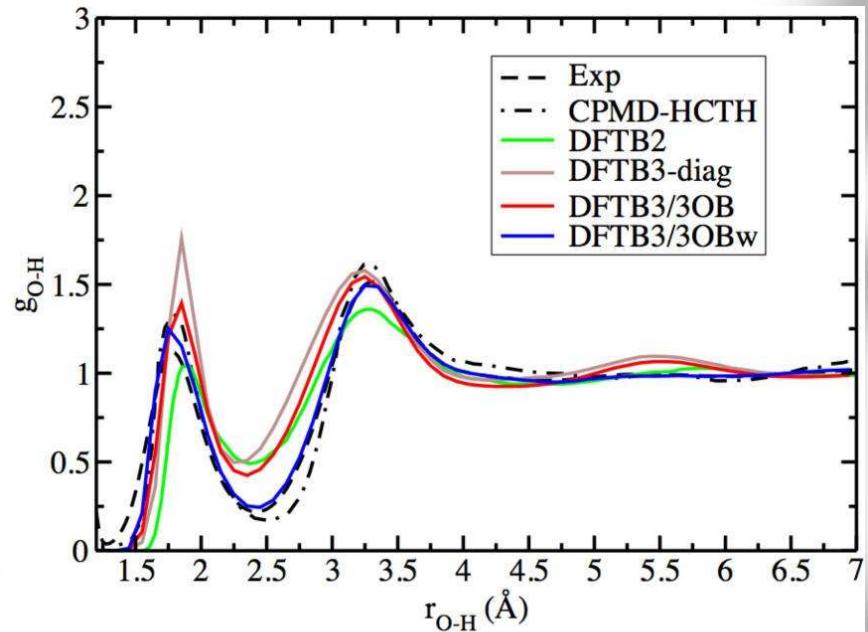
- Damping of γ_{AB} for hydrogen interactions:

$$\tilde{\gamma}_{AB} = \frac{1}{R_{AB}} - s(R_{AB}, U_A, U_B) e^{-\left(\frac{U_A+U_B}{2}\right)^{\zeta}} R_{AB}^2$$

DFTB3-QM/MM correct performance for treating water in different chemical environments



(a) g_{O-O}



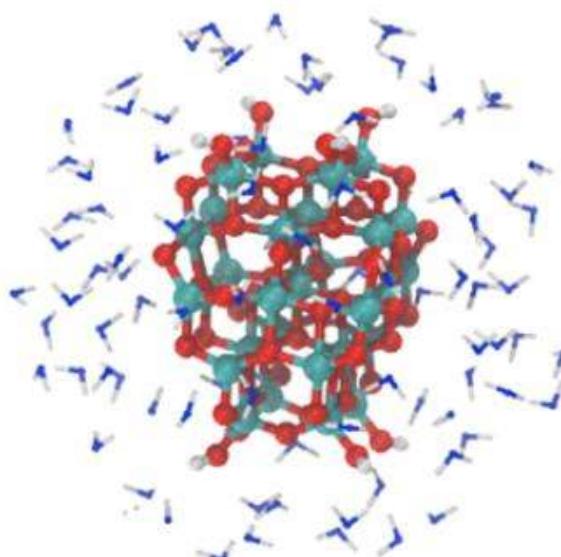
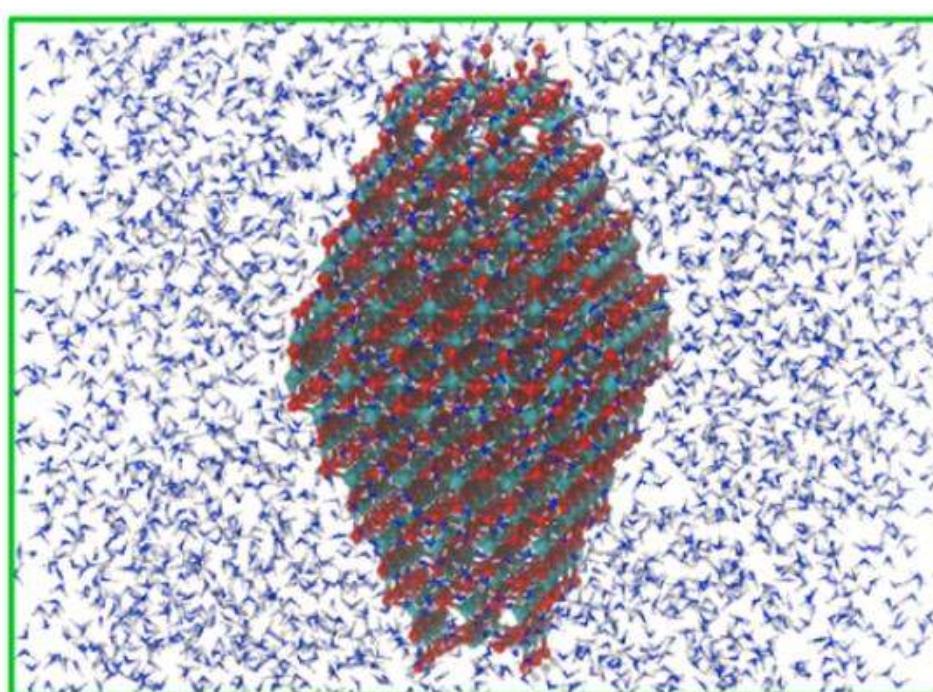
(b) g_{O-H}

Minor changes in DFTB3 substantially improve the structural properties of bulk water under ambient conditions

DOI: 10.1021/acs.jctc.7b00479

J. Chem. Theory Comput. 2017, 13, 3862–3873

Water Multilayers on TiO_2 (101) Anatase Surface: Assessment of a DFTB-Based Method

Daniele Sellì,[†] Gianluca Fazio,^{†,‡} Gotthard Seifert,[‡] and Cristiana Di Valentin^{*,†} **DFT****SCC-
DFTB**

Many-body dispersion interaction for DFTB

THE JOURNAL OF CHEMICAL PHYSICS 144, 151101 (2016)

Communication: Charge-population based dispersion interactions for molecules and materials

Martin Stöhr,^{1,2} Georg S. Michelitsch,² John C. Tully,¹ Karsten Reuter,² and Reinhard J. Maurer^{1,a)}

¹*Department of Chemistry, Yale University, New Haven, Connecticut 06520, USA*

²*Department Chemie, Technische Universität München, Lichtenbergstr. 4, D-85748 Garching, Germany*

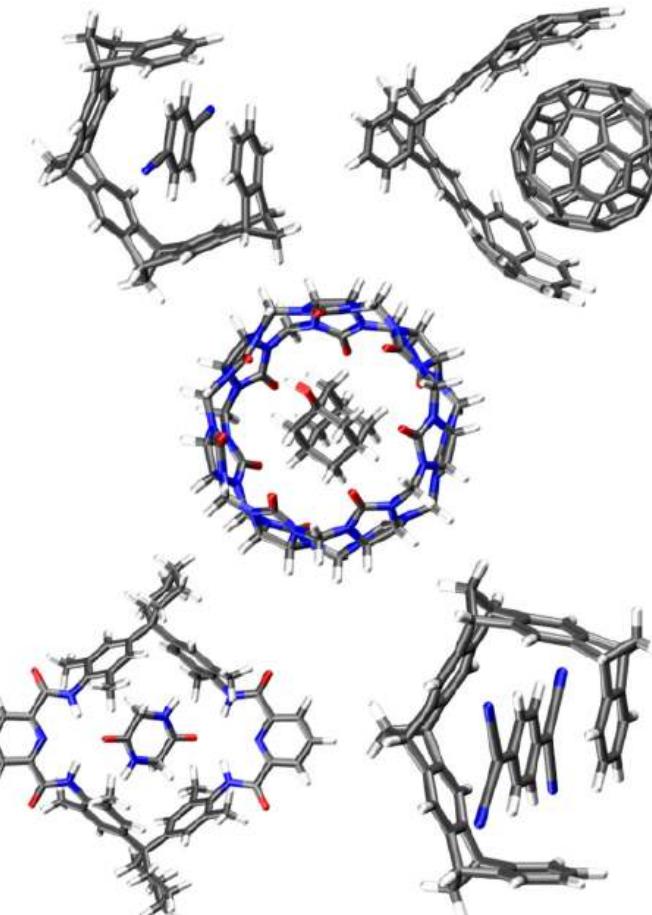
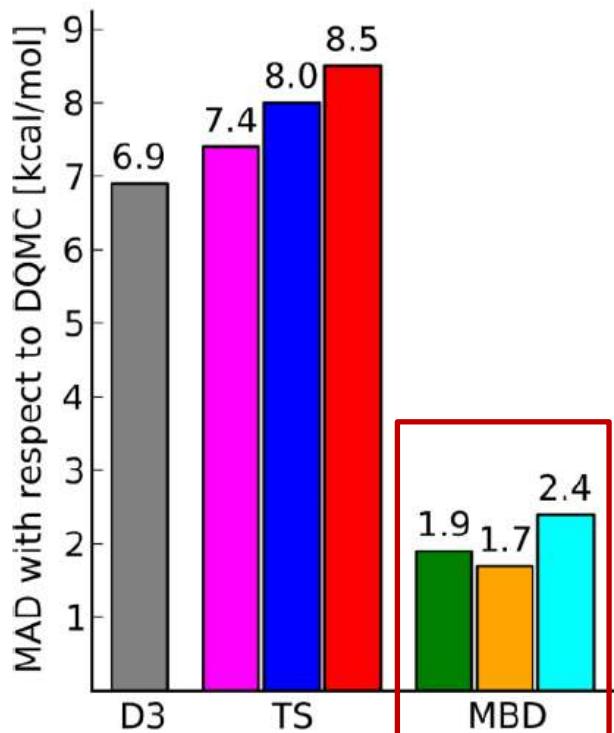
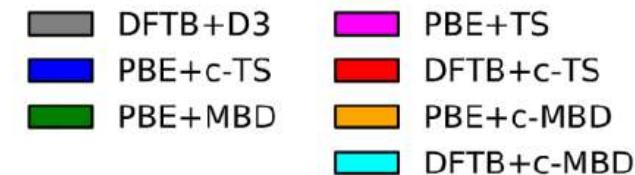
(Received 3 March 2016; accepted 8 April 2016; published online 19 April 2016)

The DFT+vdW(TS), or in short DFT+TS, scheme² represents a particularly simple and accurate method to derive dispersion interactions directly from the electron density. The dispersion interaction as given by Eq. (1) is defined via effective atom-wise dispersion parameters such as static atomic polarizabilities α_A^0 , C_6^{AA} coefficients, and van der Waals radii R_A

$$C_6^{AB} = \frac{2 C_6^{AA} C_6^{BB}}{\frac{\alpha_B^0}{\alpha_A^0} C_6^{AA} + \frac{\alpha_A^0}{\alpha_B^0} C_6^{BB}}. \quad (2)$$

$$E_{\text{disp}} = - \sum_{A < B} f_{\text{damp}}(R_{AB}, R_A, R_B) \frac{C_6^{AB}}{R_{AB}^6},$$

Many-body dipersion method for DFTB



highly improved
dispersion
interactions

molecular crystals
&
supramolecular
complexes



FIG. 2. Left: MADs in binding energies (in kcal/mol) for a selected subset of S12L complexes as obtained by different dispersion corrected approaches with respect to DQMC calculations. right: Graphical depiction of the S12L subset considered in this work. H (white), C (black), N (blue), O (red).

Molecular and
organic electronics

Extended Lagrangian Born-Oppenheimer MD: XLBOMD



A. Niklasson

A. M. N. Niklasson, J. Chem. Phys. 130, 214109 (2009)

A. M. N. Niklasson and M. J. Cawkell, Phys. Rev. B 86, 174308 (2012)

<http://www.dftb-plus.info>

MD propagation without SCF cycles → speedup 1 orders of magnitude

DFTB-XLBOMD speedup 3 orders speedup versus conventional DFTB-BO-MD

In progress for release in 2018

- density matrix via a recursive expansion of the Fermi operator
- series of generalized sparse matrix algorithms
- Linear scaling matrix inversion
- efficient parallelisation using graph-based theory

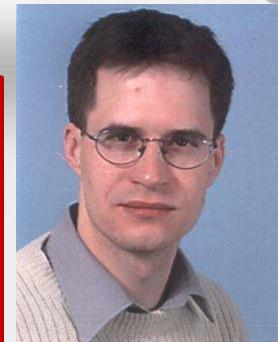


C. Negre

DFTB+ 3 more orders speedup

• 1 time step 10^4 atoms in 0.1 sec

- 100 ps QM-MD for 10^6 atoms
- Micro-second MD-simulations 10^4 atoms
-



B. Aradi

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7. Non-adiabatic Ehrenfest molecular dynamics

Review paper

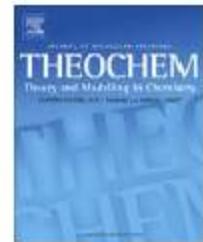
Journal of Molecular Structure: THEOCHEM 914 (2009) 38–49



Contents lists available at ScienceDirect

Journal of Molecular Structure: THEOCHEM

journal homepage: www.elsevier.com/locate/theochem



Approximate time-dependent density functional theory

T.A. Niehaus *

Bremen Center for Computational Materials Science, Am Fallturm 1a, 28359 Bremen, Germany



Linear response treatment in the frequency domain

direct propagation in the time domain - Ehrenfest MD
and an O(N) implementation in the density matrix formalism

In linear response TD-DFT

Casida's equation

$$\Omega \mathbf{F}_I = \omega_I^2 \mathbf{F}_I$$

$$\sum_{jb} \left[\omega_{ia}^2 \delta_{ij} \delta_{ab} + 4 \sqrt{\omega_{ia}} K_{ia,jb}^\Sigma \sqrt{\omega_{jb}} \right] F_{jb}^{I\Sigma} = \Omega_{I\Sigma}^2 F_{ia}^{I\Sigma}$$

ω_I

\mathbf{F}_I

excitation energies

excitation vectors

$$K_{ia,jb}^S = \int \int' \psi_i(\mathbf{r}) \psi_a(\mathbf{r}) \left(\frac{1}{|\mathbf{r} - \mathbf{r}'|} + f_{xc}[\rho](\mathbf{r}, \mathbf{r}') \right) \psi_j(\mathbf{r}') \psi_b(\mathbf{r}')$$

$$K_{ia,jb}^T = \int \int' \psi_i(\mathbf{r}) \psi_a(\mathbf{r}) \left(\frac{\delta^2 E_{xc}}{\delta m(\mathbf{r}) \delta m(\mathbf{r}')} \right) \psi_j(\mathbf{r}') \psi_b(\mathbf{r}')$$

TD-DFT: coupling matrix shifts the excitation energies

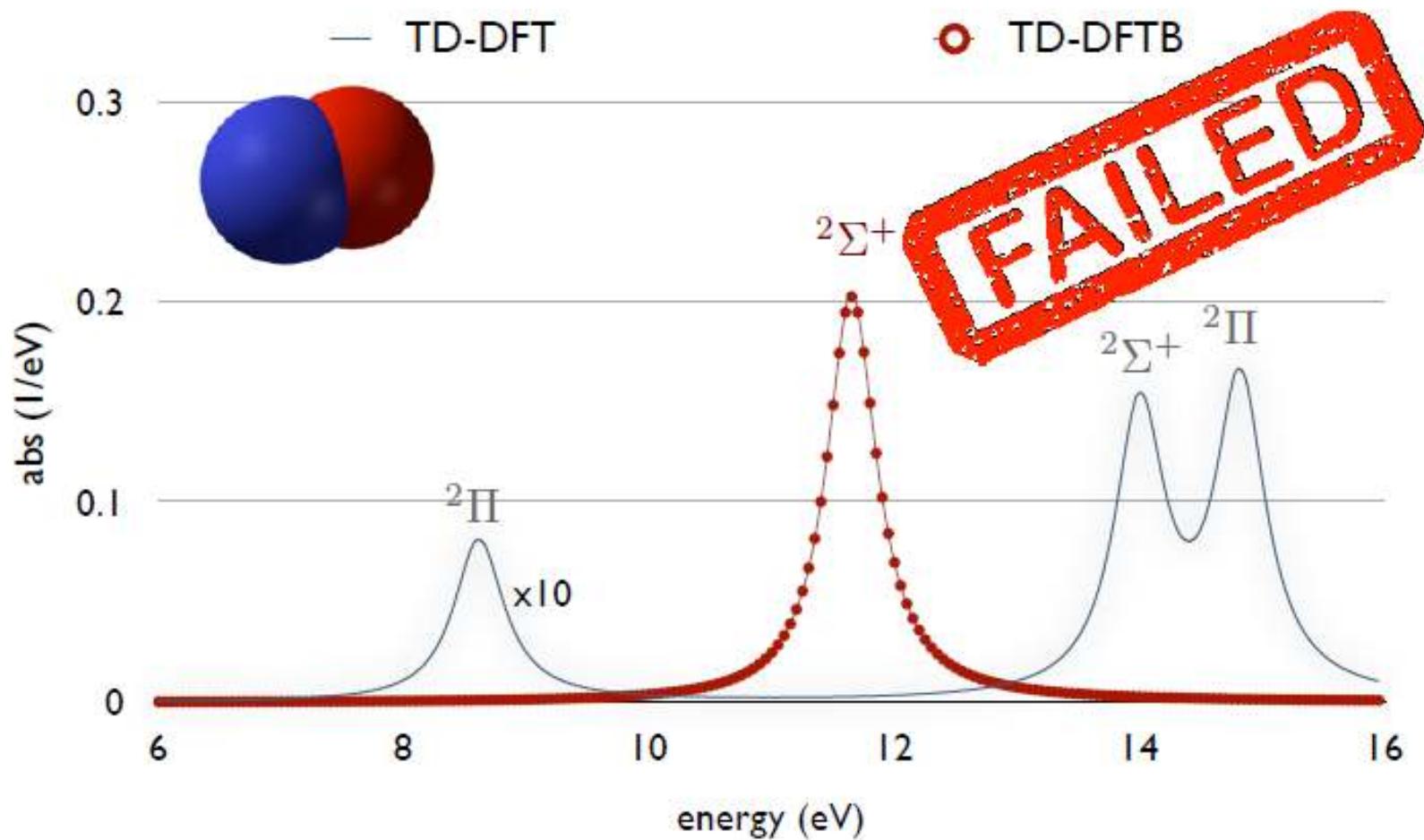
$$K_{ia\sigma}^{DFTB} = \sum_{ABll'} q_{Al}^{ia\sigma} \Gamma_{Al,Bl'}^{\sigma\tau} q_{Bl'}^{jb\tau}$$

Mulliken trans.
charges

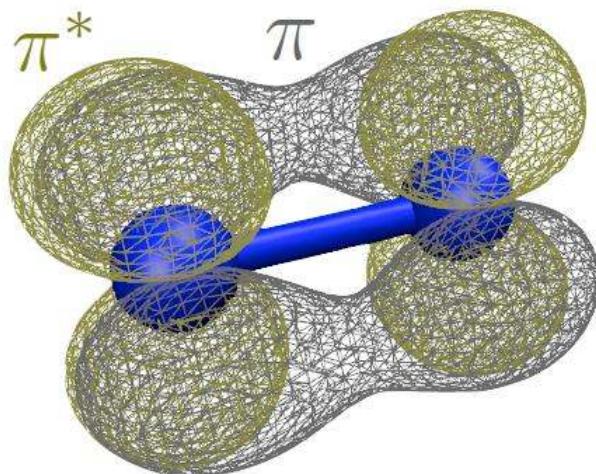
Mulliken approximation for transition dipole

$$\mathbf{d}_{ia\sigma} \approx \sum_A q_A^{ia\sigma} \mathbf{R}_A$$

Absorption spectrum of NO with TD-DFTB without corrections



TD-DFTB excitations in the Mulliken approach



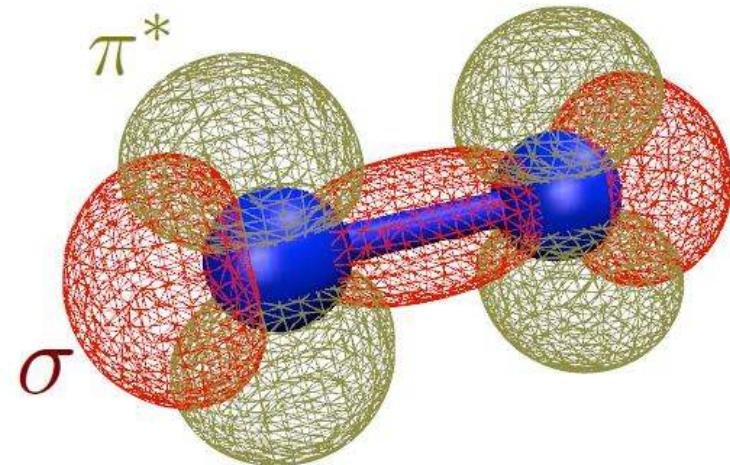
$$\pi \rightarrow \pi^*$$

$$\pi = c_{p_{1x}\pi} p_x^{(1)} + c_{p_{2x}\pi} p_x^{(2)}$$

$$\pi^* = c_{p_{1x}\pi^*} p_x^{(1)} - c_{p_{2x}\pi^*} p_x^{(2)}$$

$$\begin{aligned} q_1^{\pi\pi^*} &= \frac{1}{2} (c_{p_{1x}\pi} c_{p_{1x}\pi^*} S_{p_{1x}p_{1x}} \\ &\quad - c_{p_{1x}\pi} c_{p_{2x}\pi^*} S_{p_{1x}p_{2x}}) \end{aligned}$$

Correct coupling



$$\sigma \rightarrow \pi^*$$

$$\sigma = c_{p_{1z}\sigma} p_z^{(1)} + c_{p_{2z}\sigma} p_z^{(2)}$$

$$\pi^* = c_{p_{1x}\pi^*} p_x^{(1)} - c_{p_{2x}\pi^*} p_x^{(2)}$$

$$\begin{aligned} q_1^{\sigma\pi^*} &= \frac{1}{2} (c_{p_{1z}\sigma} c_{p_{1x}\pi^*} S_{p_{1z}p_{1x}} \\ &\quad - c_{p_{1z}\sigma} c_{p_{2x}\pi^*} S_{p_{1z}p_{2x}}) \end{aligned}$$

$$\omega_I = \omega_{\sigma\pi^*} \quad d_{\sigma\pi^*} = 0$$

Transition charges are zero – no coupling
even dipole-forbidden

Extensions of the Time-Dependent Density Functional Based Tight-Binding Approach

A. Domínguez,^{*,†} B. Aradi,[†] T. Frauenheim,[†] V. Lutsker,[‡] and T. A. Niehaus[‡]

[†]Bremen Center for Computational Materials Science, Universität Bremen, Am Fallturm 1, 28359 Bremen, Germany

[‡]Department of Theoretical Physics, University of Regensburg, 93040 Regensburg, Germany

Supporting Information

ABSTRACT: The time-dependent density functional based tight-binding (TD-DFTB) approach is generalized to account for fractional occupations. In addition, an on-site correction leads to marked qualitative and quantitative improvements over the original method. Especially, the known failure of TD-DFTB for the description of $\sigma \rightarrow \pi^*$ and $n \rightarrow \pi^*$ excitations is overcome. Benchmark calculations on a large set of organic molecules also indicate a better description of triplet states. The accuracy of the revised TD-DFTB method is found to be similar to first principles TD-DFT calculations at a highly reduced computational cost. As a side issue, we also discuss the generalization of the TD-DFTB method to spin-polarized systems. In contrast to an earlier study, we obtain a formalism that is fully consistent with the use of local exchange-correlation functionals in the ground state DFTB method.

abs (1/eV)



Onsite correction: improved accuracy for excitation energies in TD-DFTB

- Mulliken-approximation for orbital products:

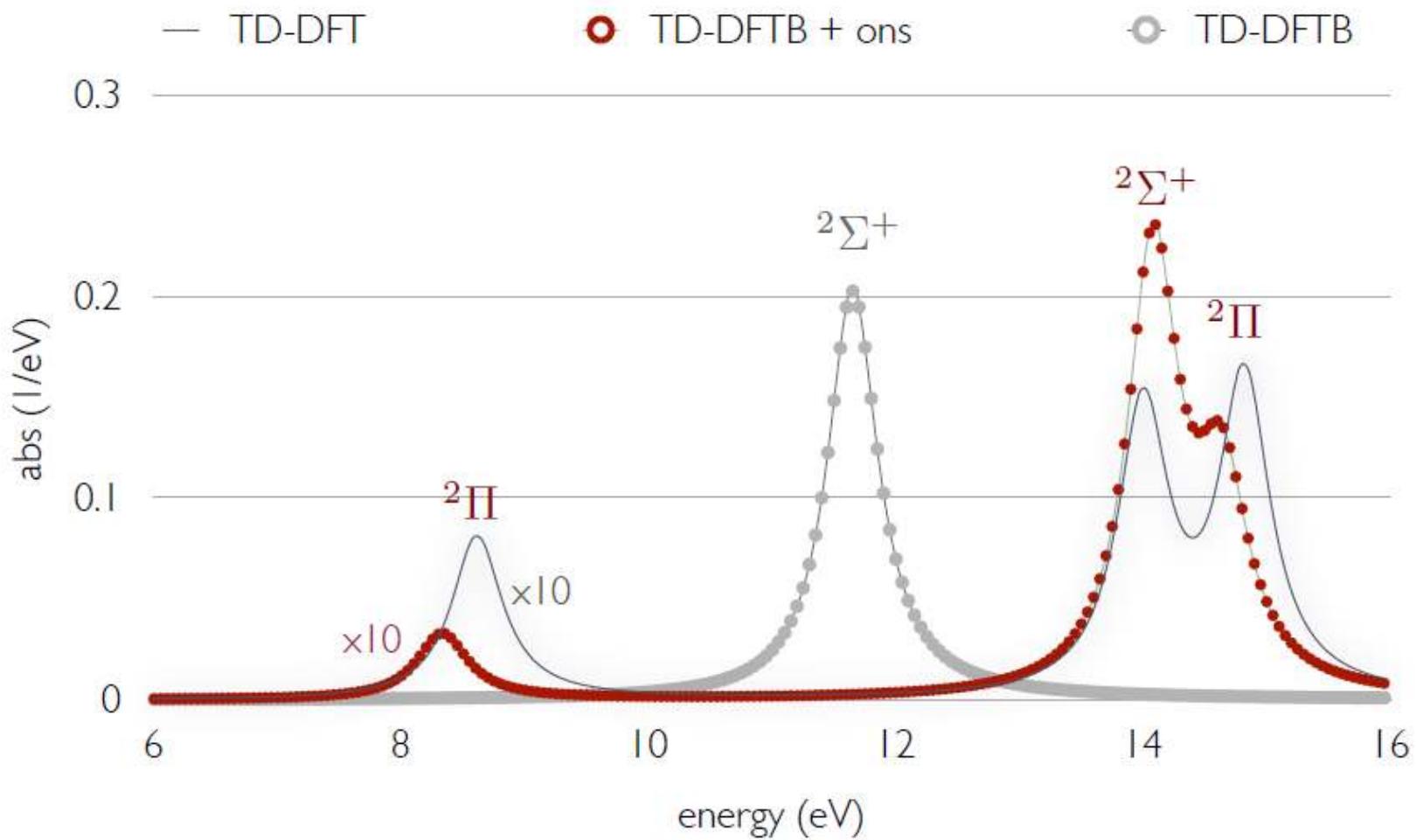
$$\phi_\mu(\mathbf{r})\phi_\nu(\mathbf{r}) \approx \frac{1}{2}S_{\mu\nu}(|\phi_\mu(\mathbf{r})|^2 + |\phi_\nu(\mathbf{r})|^2)$$

- Going beyond Mulliken-approximation:

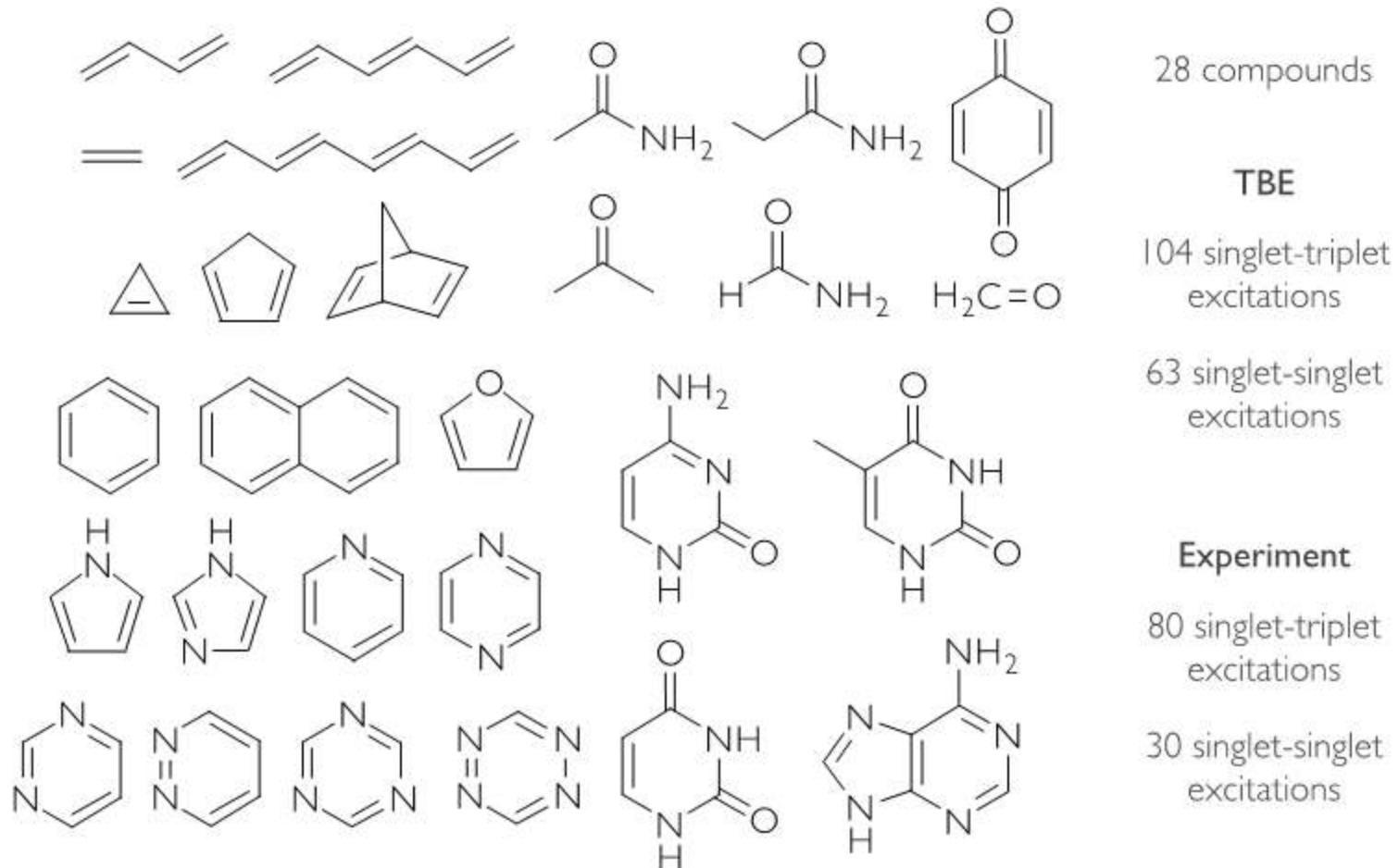
$$E_2 = \frac{1}{2} \left[\sum_{\mu\nu} \Delta \tilde{P}_{\mu\mu}(\mu\mu|\nu\nu) \Delta \tilde{P}_{\nu\nu} \right. \\ \left. + \sum_A \sum_{\mu,\nu_A}^{\mu \neq \nu} \Delta \tilde{P}_{\mu\nu}(\mu\nu|\mu\nu) \Delta \tilde{P}_{\mu\nu} + \dots \right]$$

$$\Delta \tilde{P} = \Delta P S$$

Absorption spectrum of NO with onsite corrections

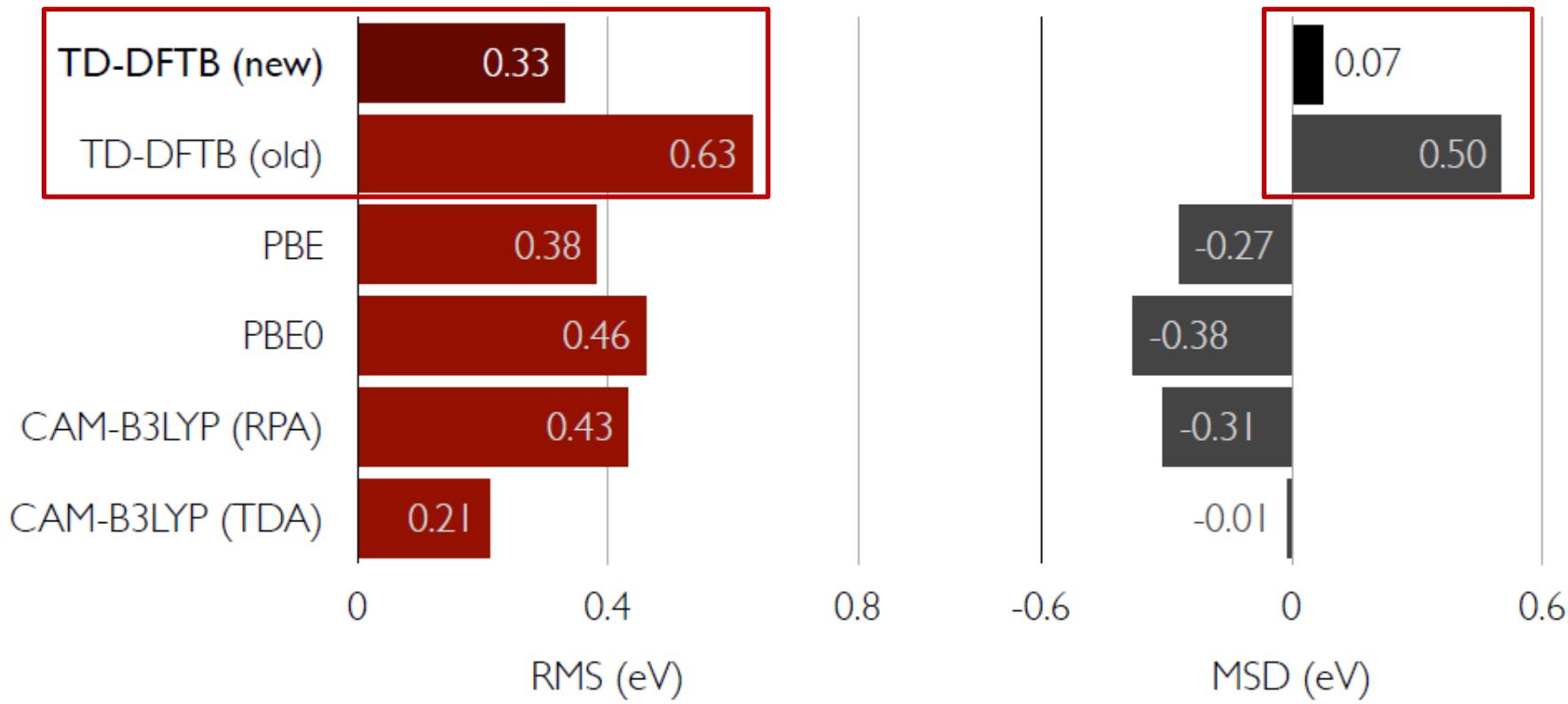


Performance – Thiel's benchmark set



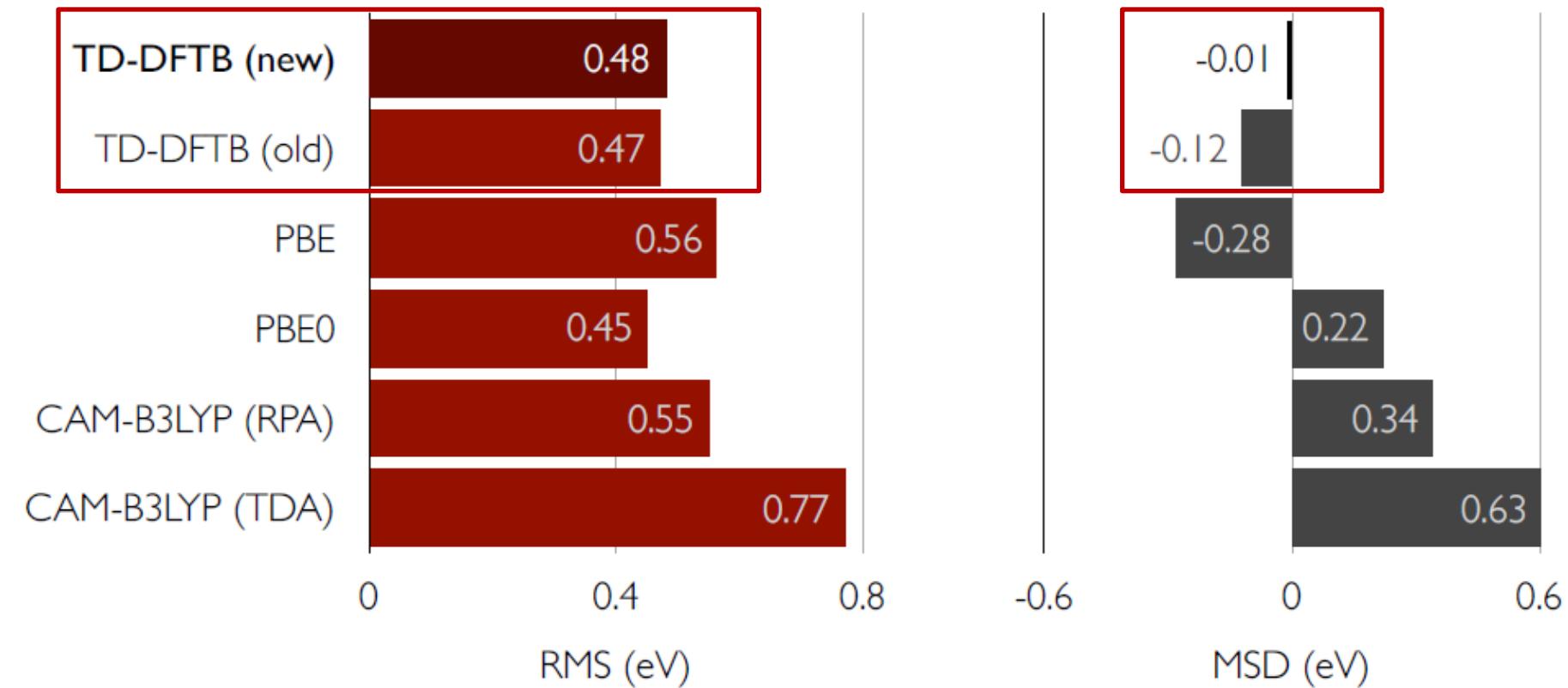
Singlet and triplet vertical excitations compared to TD-DFT PBE, PBE0, CAM-B3LYP

RMS error and MSD for singlet-triplet transition energies



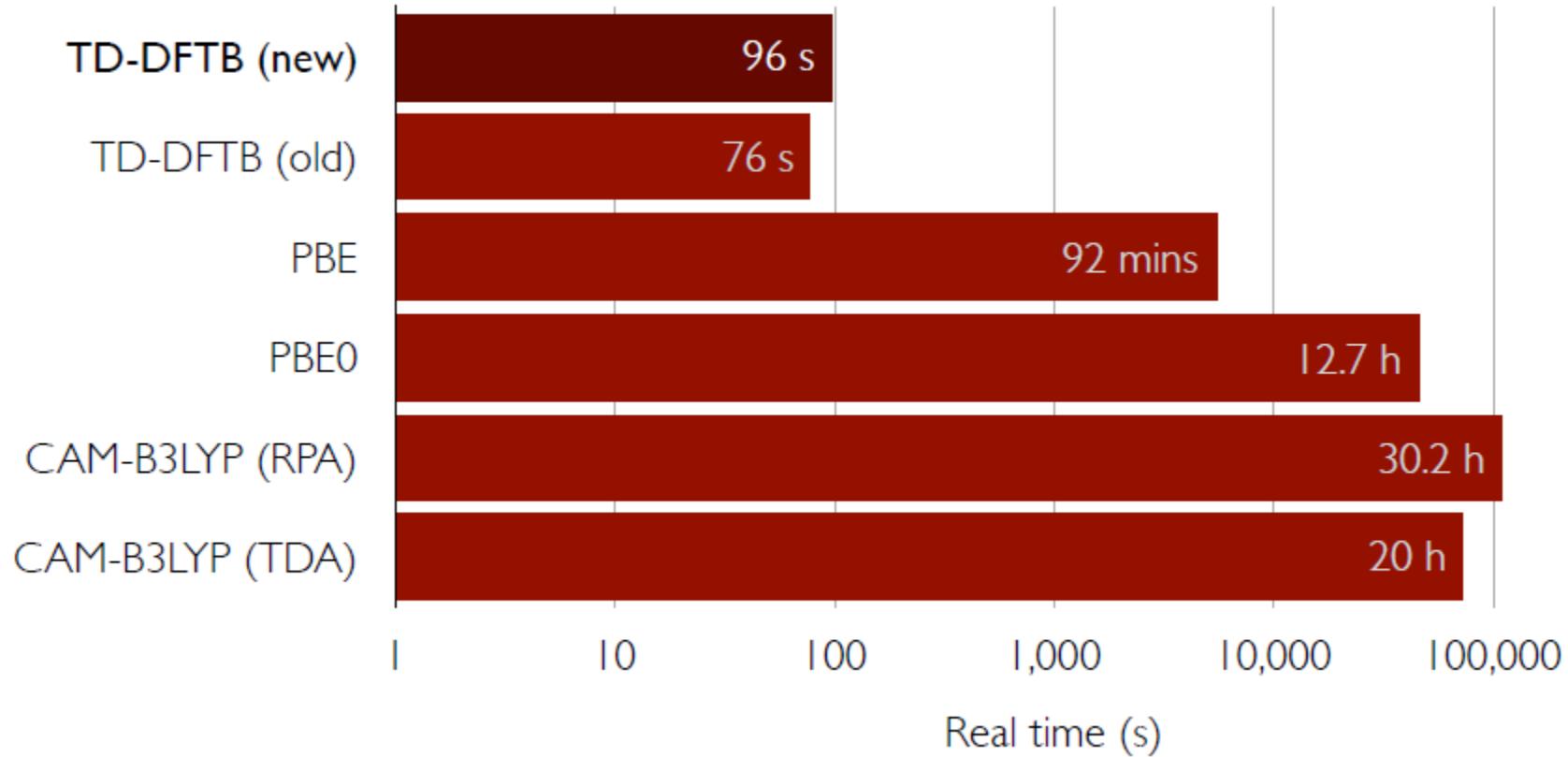
Thiel's benchmark set compared to **experimental data**

RMS error and MSD for singlet-singlet transition energies



Thiel's benchmark set compared to **experimental data**

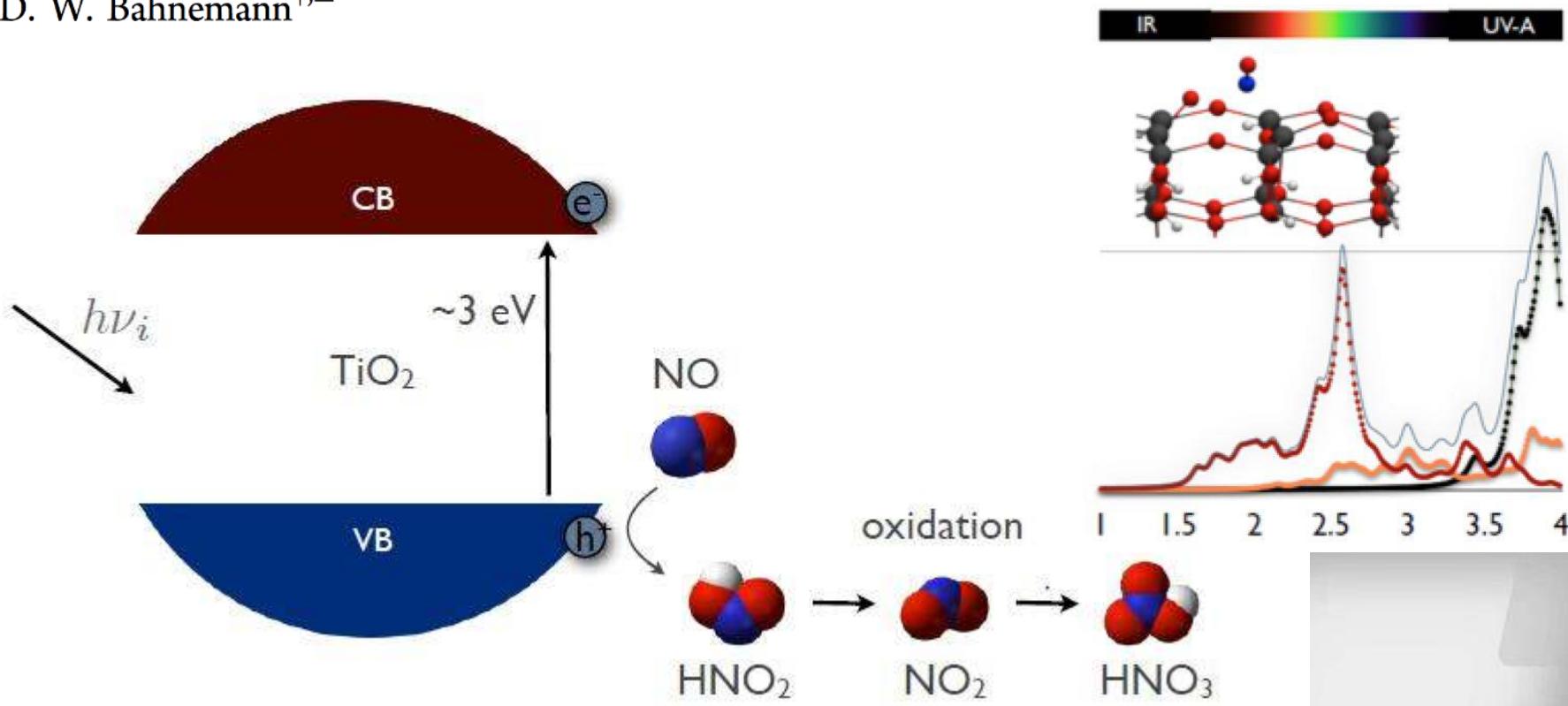
Total wall clock time Thiel's set singlet and triplets excitations



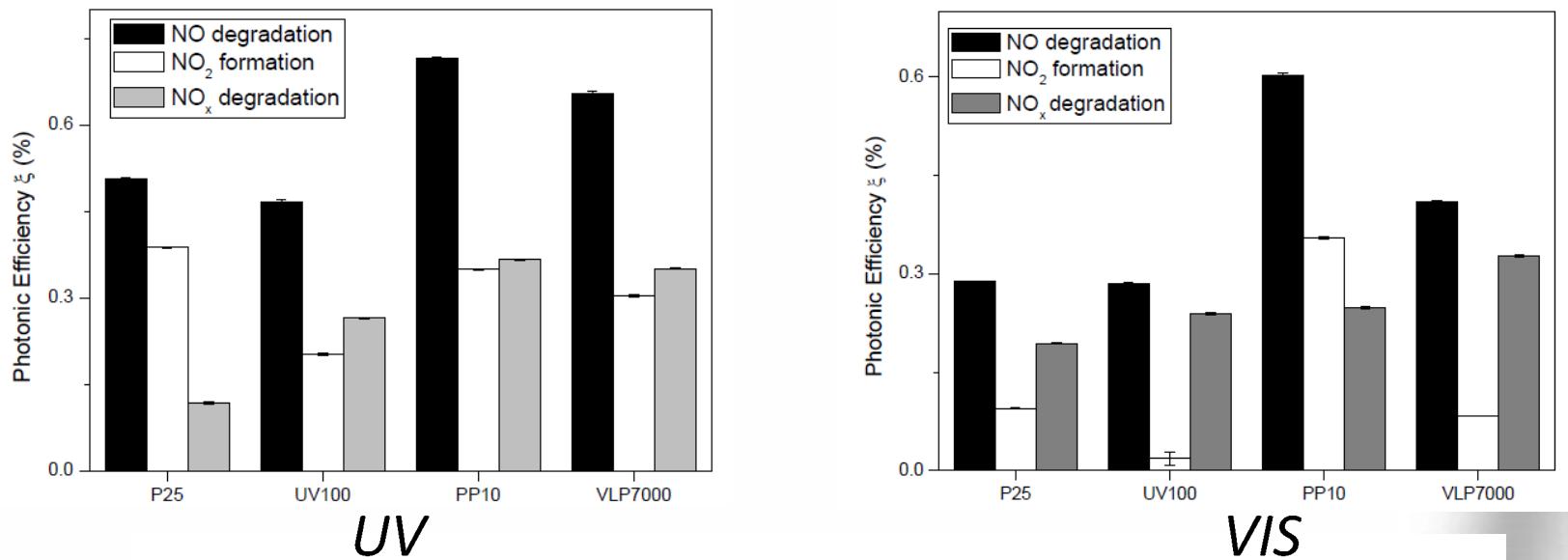
Thiel's benchmark subset

Nitrogen(II) Oxide Charge Transfer Complexes on TiO₂: A New Source for Visible-Light Activity

J. Freitag,[†] A. Domínguez,^{*,‡} T. A. Niehaus,[¶] A. Hülsewig,[§] R. Dillert,[†] T. Frauenheim,[‡] and D. W. Bahnemann^{†,⊥}



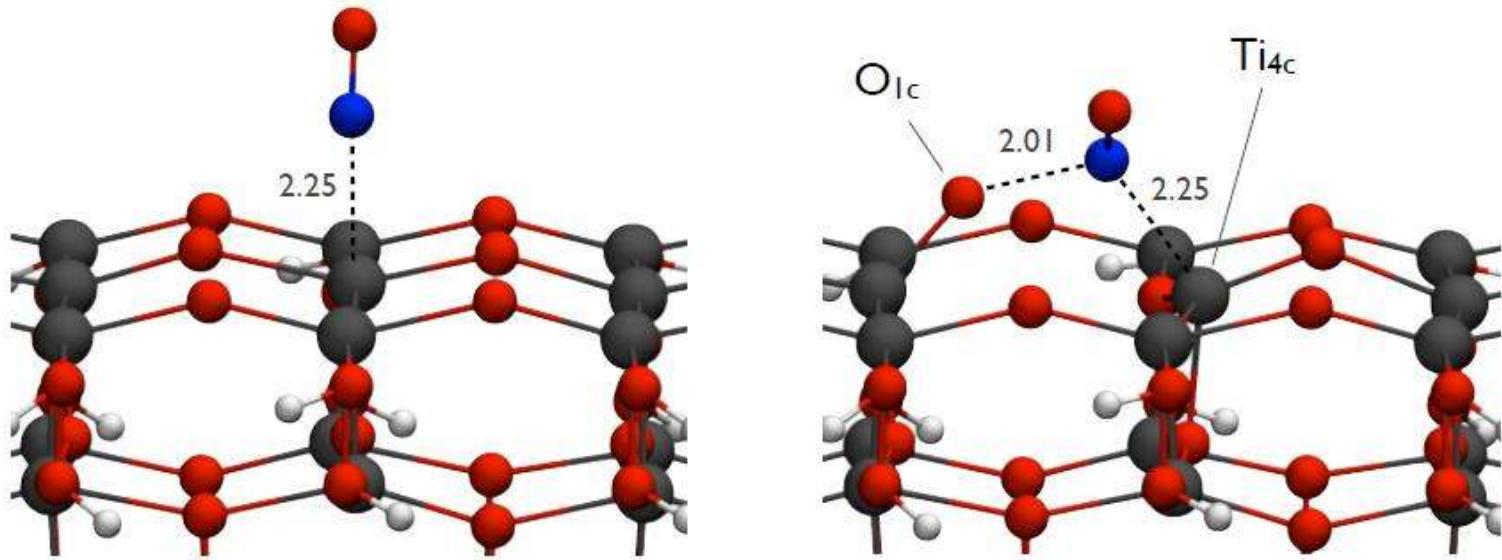
Photonic efficiencies of four TiO_2 powders under UV and VIS



| TiO_2 powder | Selectivity (UV) /% | Selectivity S (Visible) /% |
|-----------------------|---------------------|----------------------------|
| P25 | 23.44 | 67.03 |
| UV100 | 56.75 | 83.62 |
| PP10 | 51.51 | 41.15 |
| VLP 7000 | 53.51 | 79.77 |

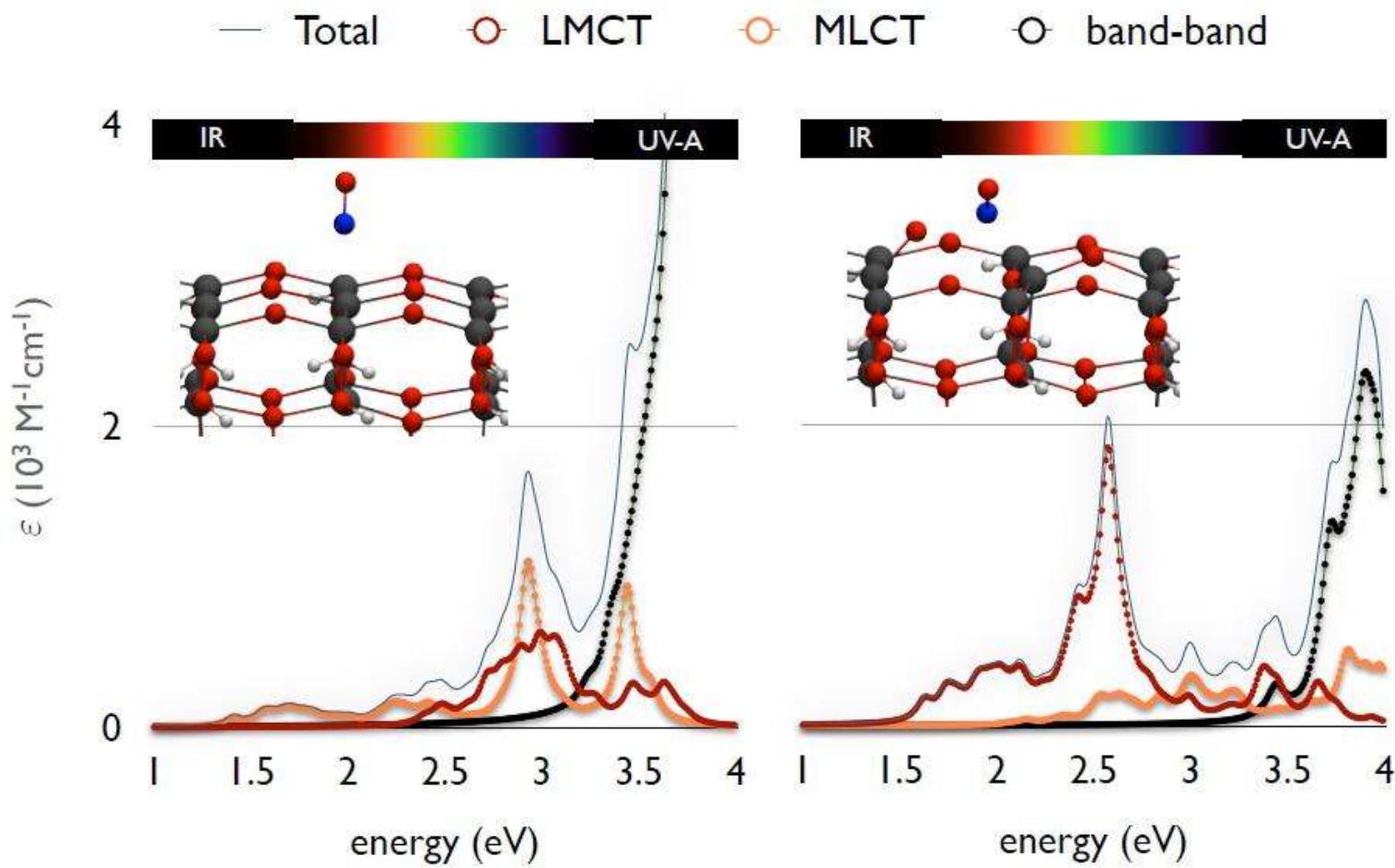
Pollutant – TiO_2 hybrid complexes are photo-active in the visible light

Two stable NO adsorption sites on anatase TiO_2



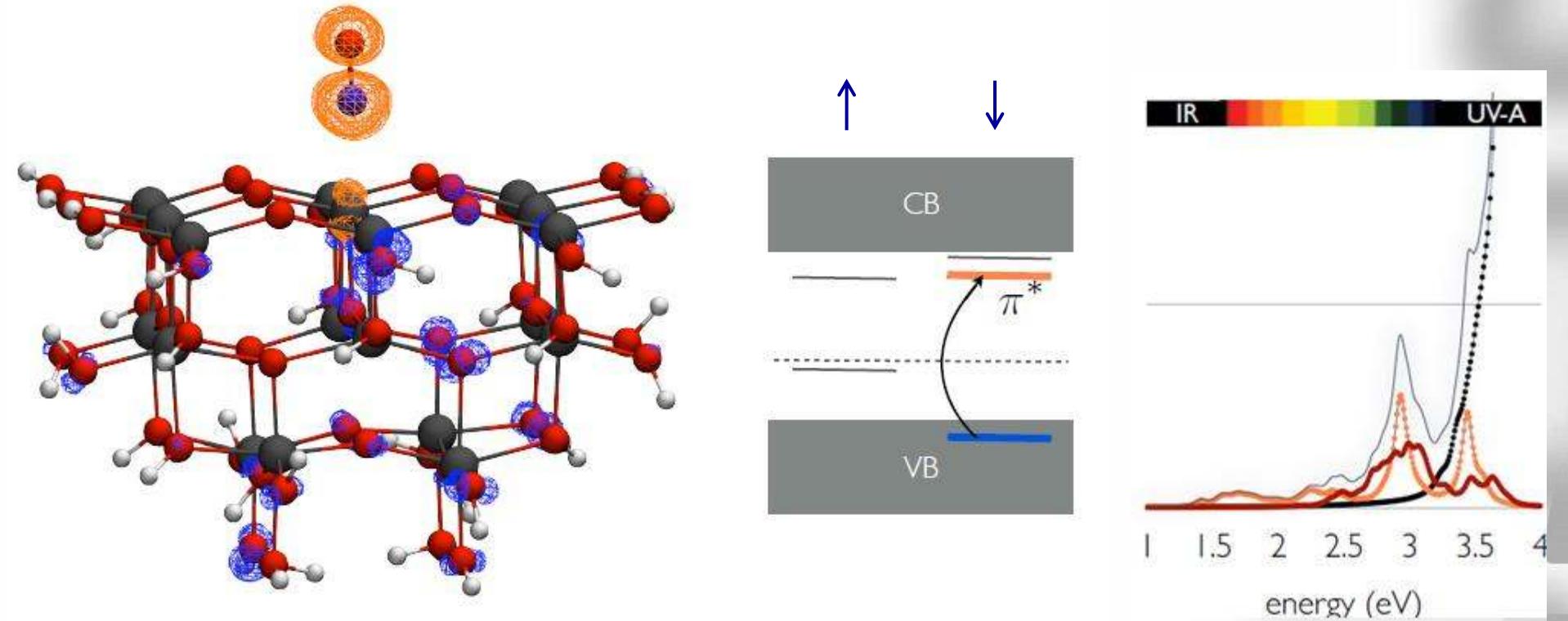
Scanning NO-adsorption for most stable sites on anatase (110)

Two stable NO adsorption sites on anatase TiO_2



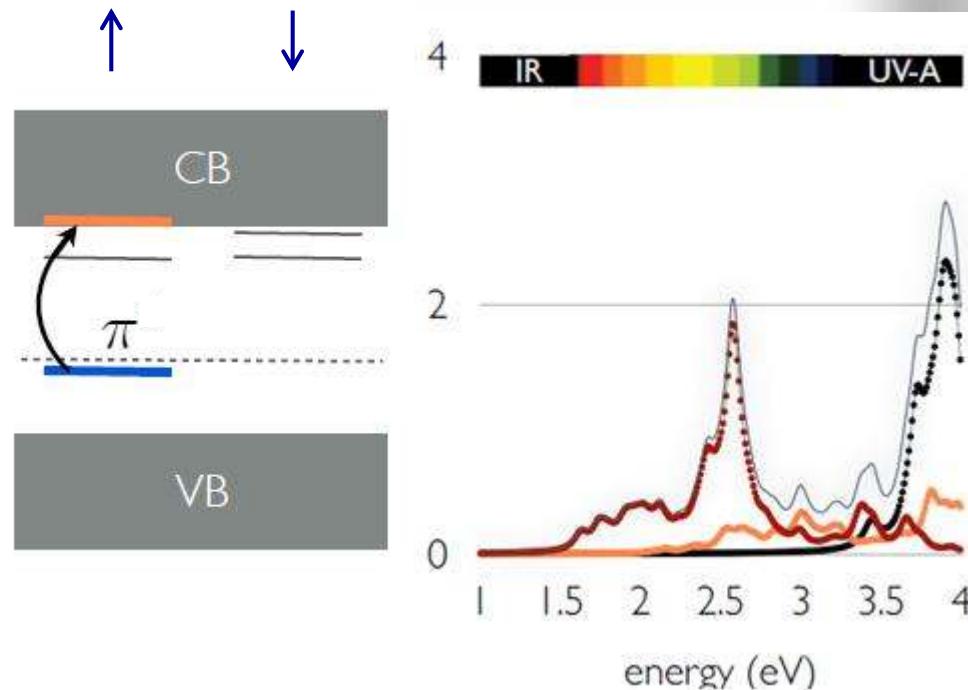
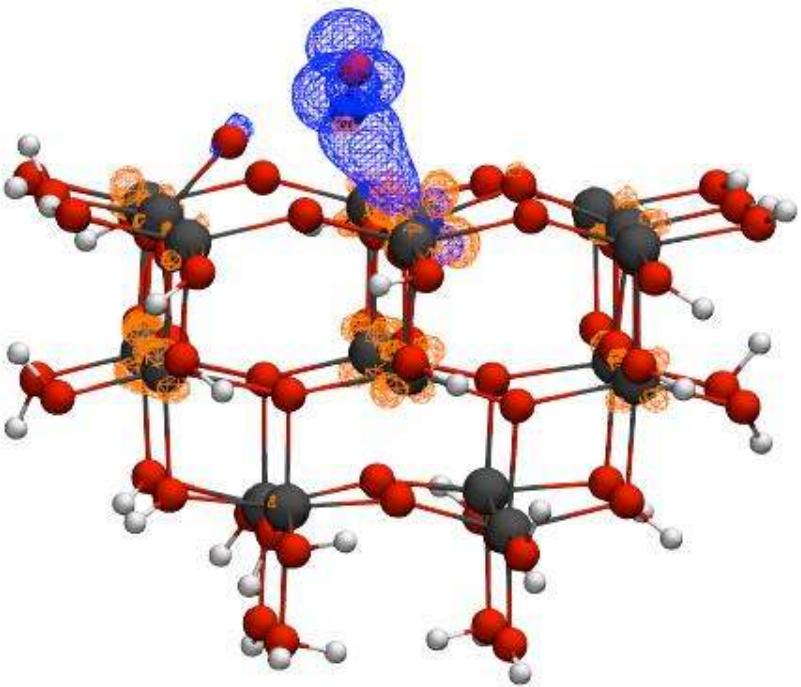
Strongly enhanced visible light activity

NO adsorption spectra on anatase TiO_2 (001) surface



Charge transfer from TiO_2 valence band to NO- π^* molecular orbital

NO adsorption spectra on anatase TiO_2 surface



Charge transfer from NO- π orbital to TiO_2 conduction band

Freitag, Dominguez, et al. J. Phys. Chem. C, 119 (2015) 4488

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5. NO-reduction on TiO_2 surfaces
6. Charge transfer excitations using pp-DFTB
7. Non-adiabatic molecular dynamics

Nonadiabatic Molecular Dynamics for Thousand Atom Systems: A Tight-Binding Approach toward PYXAID

Sougata Pal,[†] Dhara J. Trivedi,^{||} Alexey V. Akimov,[§] Bálint Aradi,[‡] Thomas Frauenheim,[‡] and Oleg V. Prezhdo^{*,†}

[†]Department of Chemistry, University of Southern California, Los Angeles, California 90089, United States

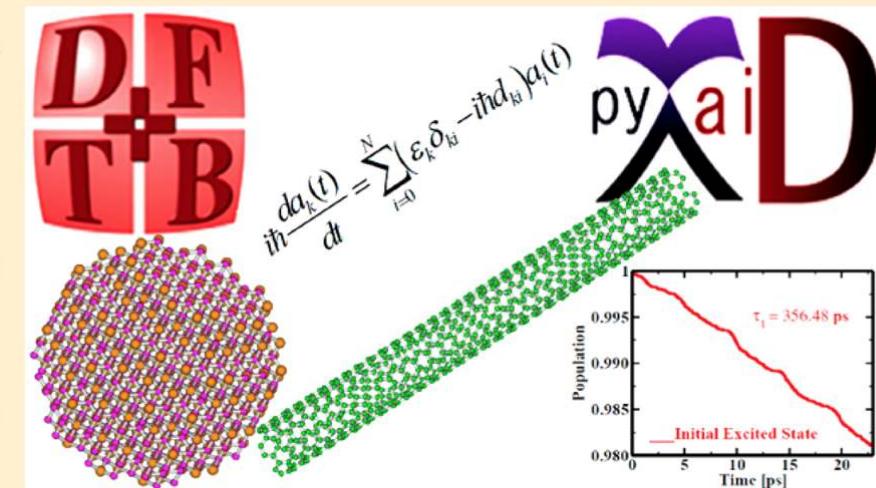
^{||}Department of Physics and Astronomy, University of Rochester, Rochester, New York 14627, United States

[§]Department of Chemistry, University at Buffalo, The State University of New York, Buffalo, New York 14260-3000, United States

[‡]Bremen Center for Computational Materials Science, Universität Bremen, Otto-Hahn-Alle 1, 28359 Bremen, Germany

ABSTRACT: Excited state dynamics at the nanoscale requires treatment of systems involving hundreds and thousands of atoms. In the majority of cases, depending on the process under investigation, the electronic structure component of the calculation constitutes the computation bottleneck. We developed an efficient approach for simulating nonadiabatic molecular dynamics (NA-MD) of large systems in the framework of the self-consistent charge density functional combined SH) and techniques for the Python simulation designed to

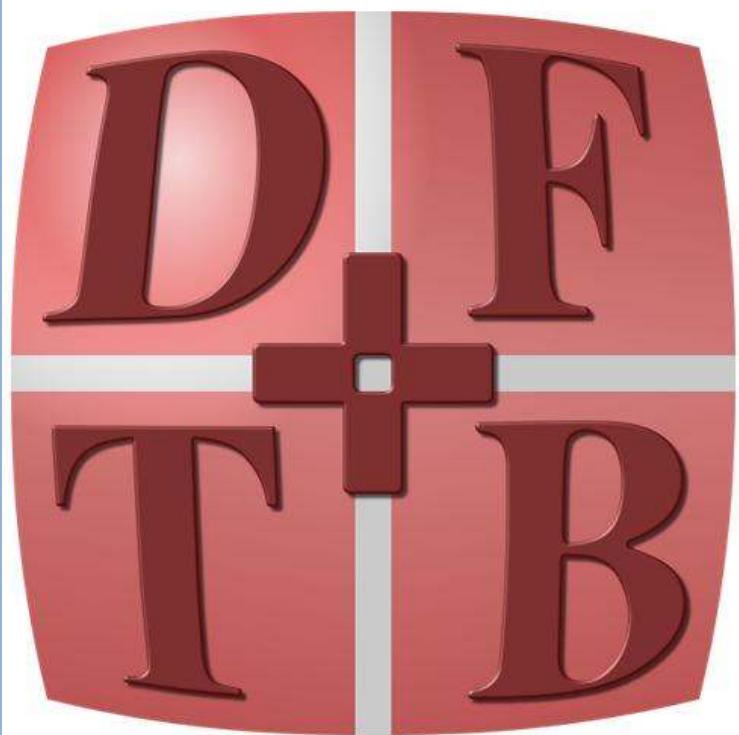
developed approach is tested with *ab initio* DFT and experimental data, by nonradiative electron–hole recombination in a CdSe quantum dot and the unique is capable of treating accurately and efficiently excitation dynamics in tight computational resources.



DFTB+ as electronic structure driving engine for NAMD in PYXAID

- Adiabatic electronic state energies
- NA couplings, d_{ki} ,
- Interatomic forces acting on the nuclei

as essential input quantities for NA-MD simulations



$$i\hbar \frac{dc_k(t)}{dt} = \sum_{i=0}^N (\varepsilon_k \delta_{ki} - i\hbar d_{ki}) c_i(t)$$

where

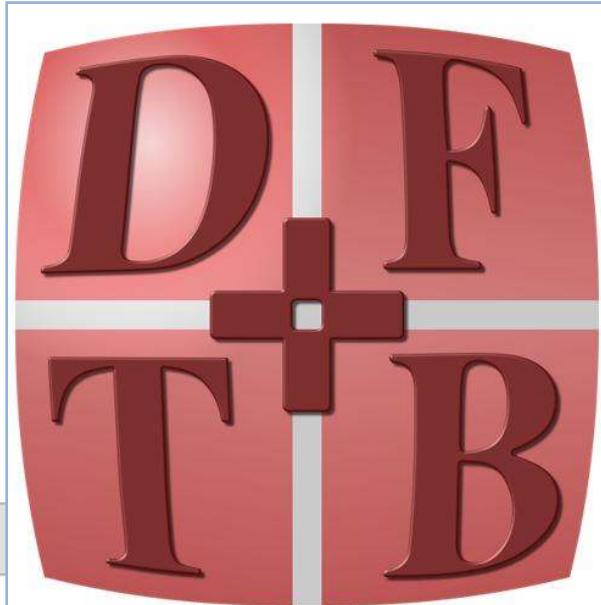
$$d_{ki} = \left\langle \phi_k(r, R(t)) \left| \frac{\partial \phi_i(r, R(t))}{\partial t} \right. \right\rangle$$

DFTB+ as driving engine for NAMD in NEXMD (Los Alamos)

- NEXMD with various surface hopping techniques
- Real-time NAMD
- Based on excited state determinants
- Available in combination with SE methods, like AM_x

Interface to AMBER force field: **excited state QM/MM**

Sergei Tretiak LANL



Adrian Roitberg U Florida



NEW implementation of real time TDDFTB: electron-ion dynamics

Christian Sanchez (right), Franco Bonafe, University of Cordoba

Numerical propagation of density matrix according to
Liouville-von Neumann equation

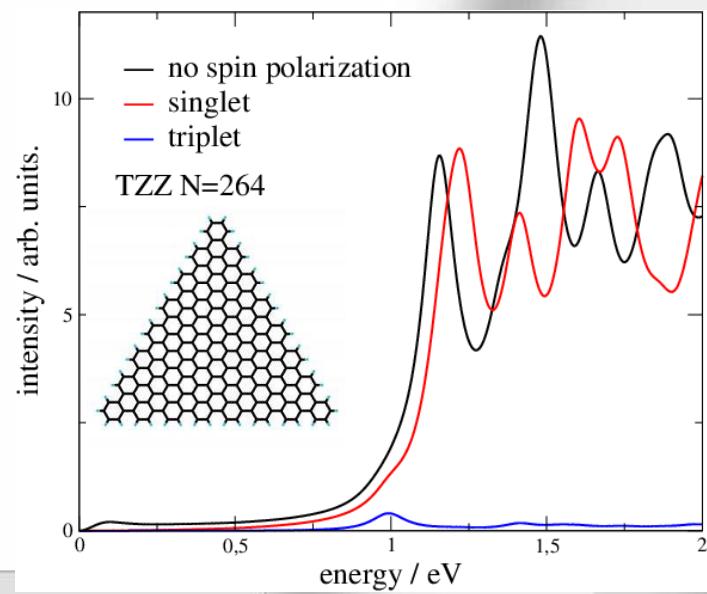
$$\dot{\rho} = -i(S^{-1}H\rho - \rho HS^{-1}) \rightarrow \rho_{i+1} = \rho_{i-1} + 2\Delta t \dot{\rho}_i$$
$$H_{\mu\nu} = H_{\mu\nu}^0 + \frac{1}{2}S_{\mu\nu} \sum_K (\gamma_{IK} + \gamma_{JK})\Delta q_K, \quad \mu \in I \quad \nu \in J.$$

Absorption spectra are calculated by the polarizability tensor obtained
by Fourier transform of the dipole moment, after a proper perturbation

$$\mu(t) = \int_{-\infty}^{\infty} \alpha(t-\tau) E(\tau) d\tau$$
$$E(t) = E_0 \delta(t - t_0)$$

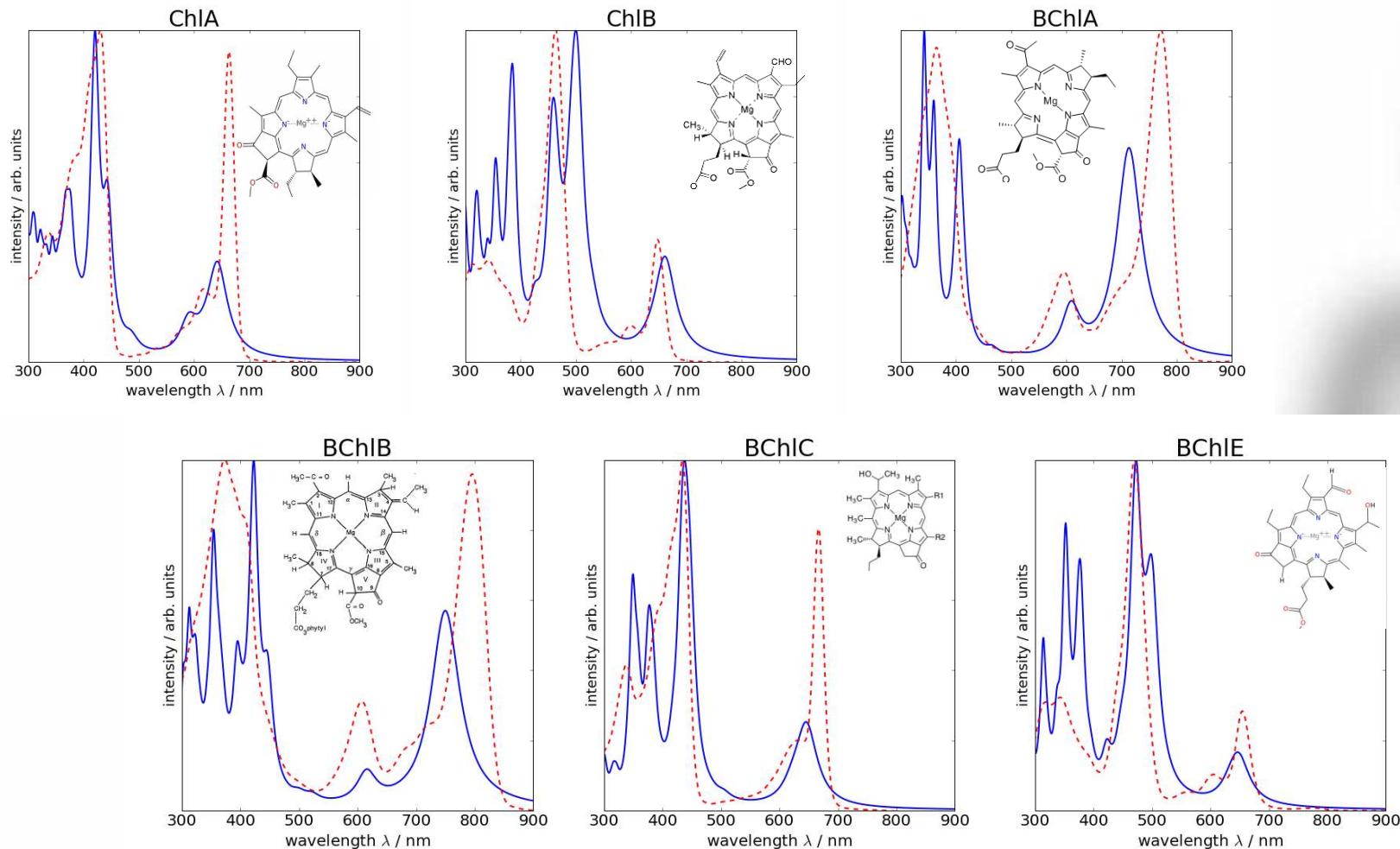
Initial kick determines type of spectrum:

- Electric field: singlet spectrum
- Magnetic field: triplet spectrum



Zigzag graphene nanoflake

Absorption spectra of photosynthetic pigments



Experimental data in agreement with
calculated frequencies and intensities

— Experimental
— Calculated with TDDFTB in DFTB+

Non-adiabatic Ehrenfest dynamics

Semi-classical treatment: **classical nuclei, quantum electrons.**

Equation of motion of density matrices includes
non-adiabatic coupling matrix and velocity dependent terms:

$$\dot{\rho} = -i(S^{-1}H\rho - \rho HS^{-1}) - (S^{-1}\tilde{D}\rho + \rho\tilde{D}S^{-1})$$

Ion dynamics by **velocity-Verlet**:

$$\mathbf{R}_A(t + \Delta t) = \mathbf{R}_A(t) + \dot{\mathbf{R}}_A(t)\Delta t + \frac{1}{2m}\mathbf{F}_A(t)\Delta t^2 \quad \tilde{D}_{kl} = \dot{\mathbf{R}}_A \cdot \langle \phi_k | \nabla_A \phi_l \rangle$$
$$\dot{\mathbf{R}}_A(t + \Delta t) = \dot{\mathbf{R}}_A(t) + \frac{1}{2m}(\mathbf{F}_A(t) + \mathbf{F}_A(t + \Delta t))\Delta t \quad v_A \cdot \nabla_A S_{kl}$$

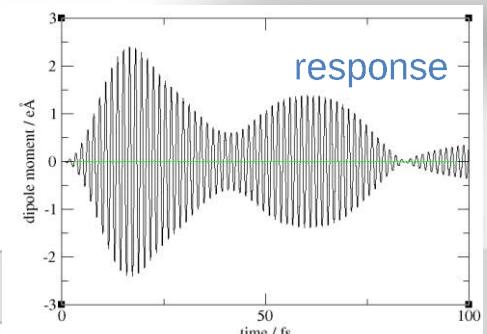
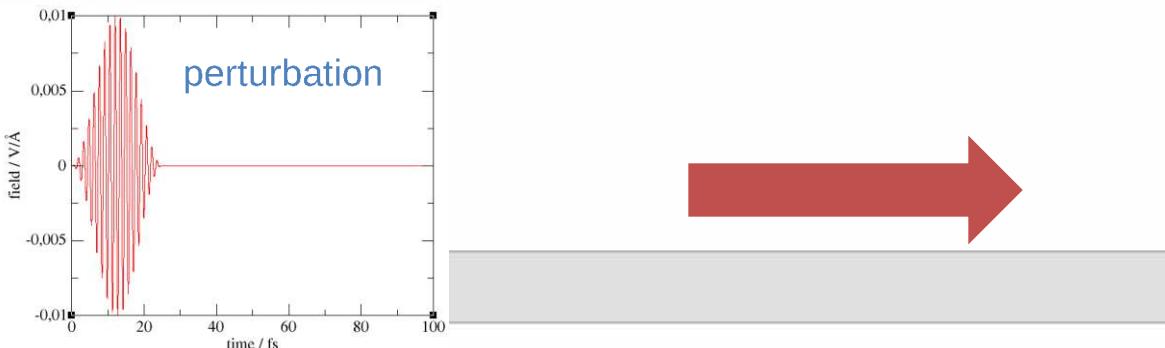
Todorov

The electric field is added as any external perturbation to the hamiltonian:

$$H = H^1 + \frac{1}{2}(Sf + fS) \quad \text{where} \quad f = -e\mathbf{E}(t) \cdot \hat{\mathbf{r}}$$

For a \sin^2 laser pulse of length τ with frequency ω , e.g., the electric field is:

$$\mathbf{E}(t) = E_0 \sin^2(\pi t/\tau) \sin(\omega t)(1 - \Theta(\tau))$$



Impulsive breathing mode excitations in Ag and Au NPs

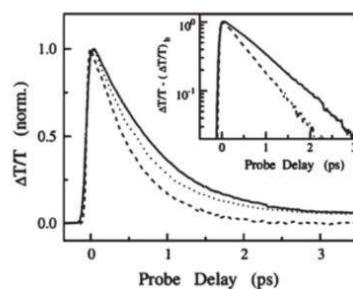
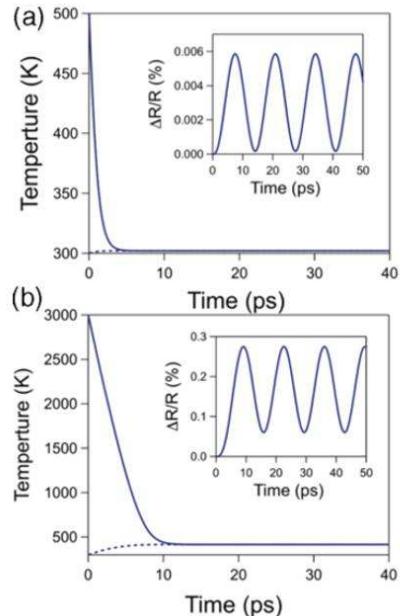
Motivation by experimental studies

CHEMICAL REVIEWS

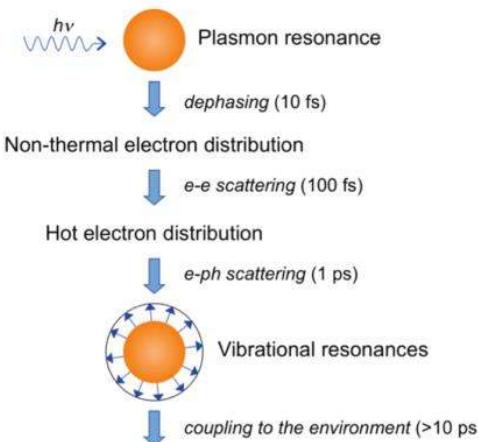
Optical Studies of Dynamics in Noble Metal Nanostructures

Gregory V. Hartland*

Department of Chemistry and Biochemistry, University of Notre Dame, Notre Dame, Indiana 46556-5670, United States



Scheme 1. Sequence of Events and Approximate Time Scales Following Absorption of Photons by a Metal Nanoparticle



J. Phys. Chem. A 2000, 104, 4321–4326

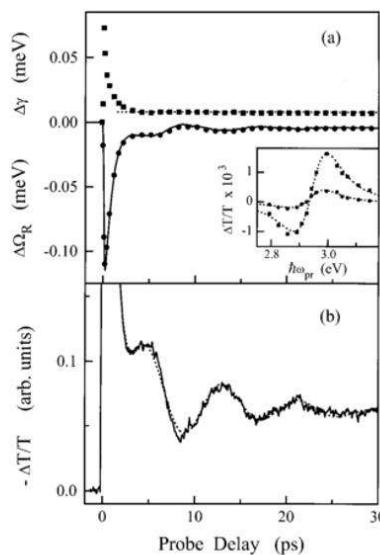
Acoustic Vibration of Metal Films and Nanoparticles

N. Del Fatti, C. Voisin, D. Christofilos, F. Vallée,* and C. Flytzanis

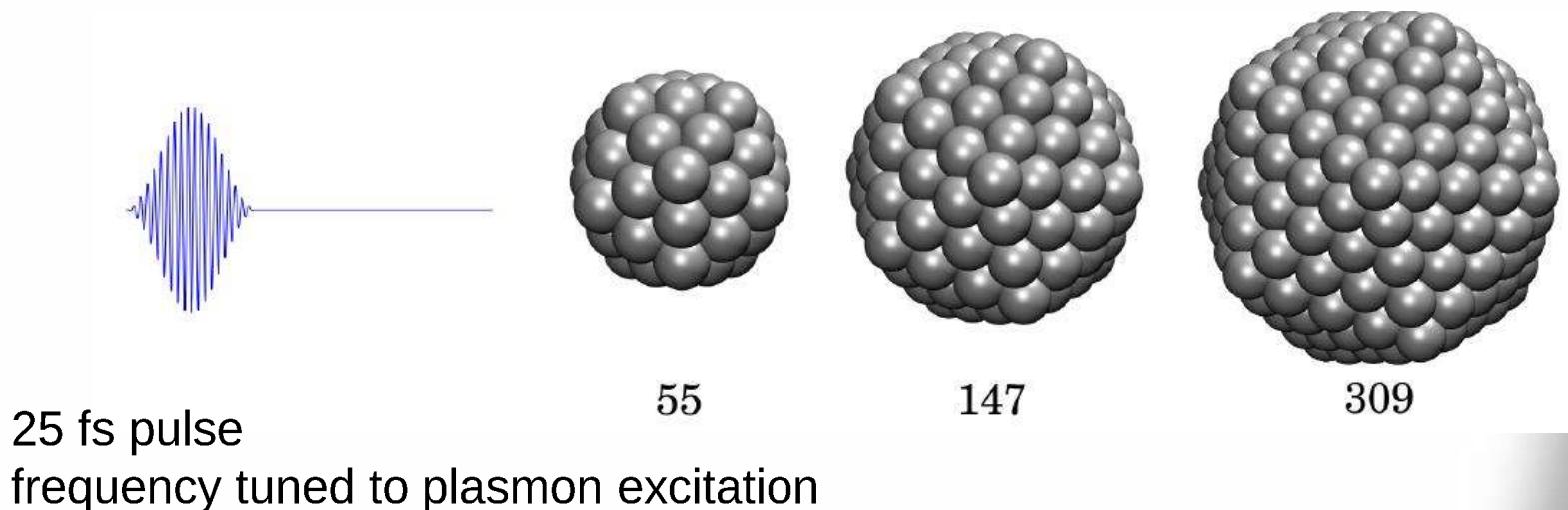
Laboratoire d'Optique Quantique du CNRS, Ecole Polytechnique, 91128 Palaiseau Cedex, France

Received: November 16, 1999; In Final Form: January 27, 2000

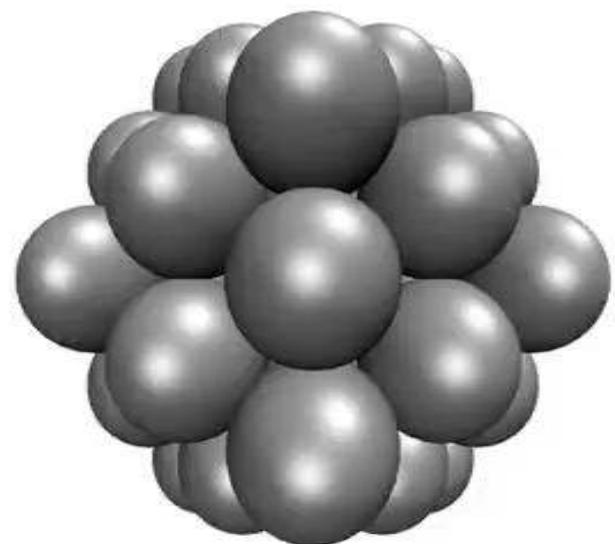
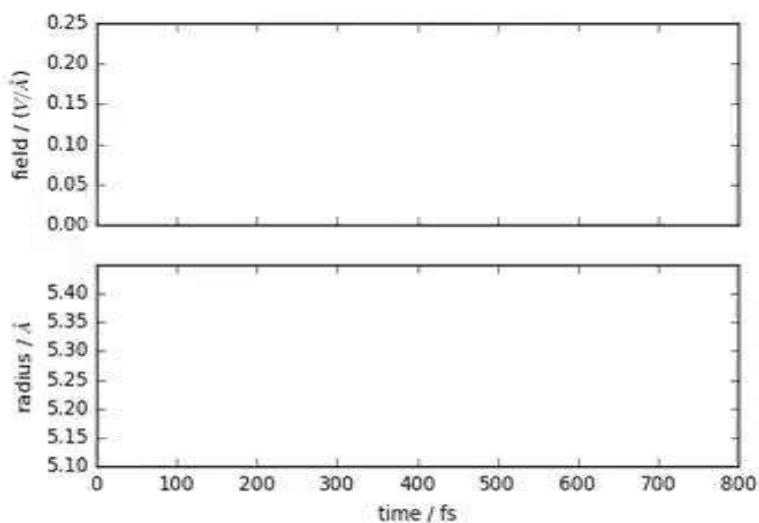
J. Phys. Chem. A, Vol. 104, No. 18, 2000 4323



Impulsive breathing mode excitation in Ag and Au NPs



25 fs pulse
frequency tuned to plasmon excitation



Ag: Change in radius versus field strength

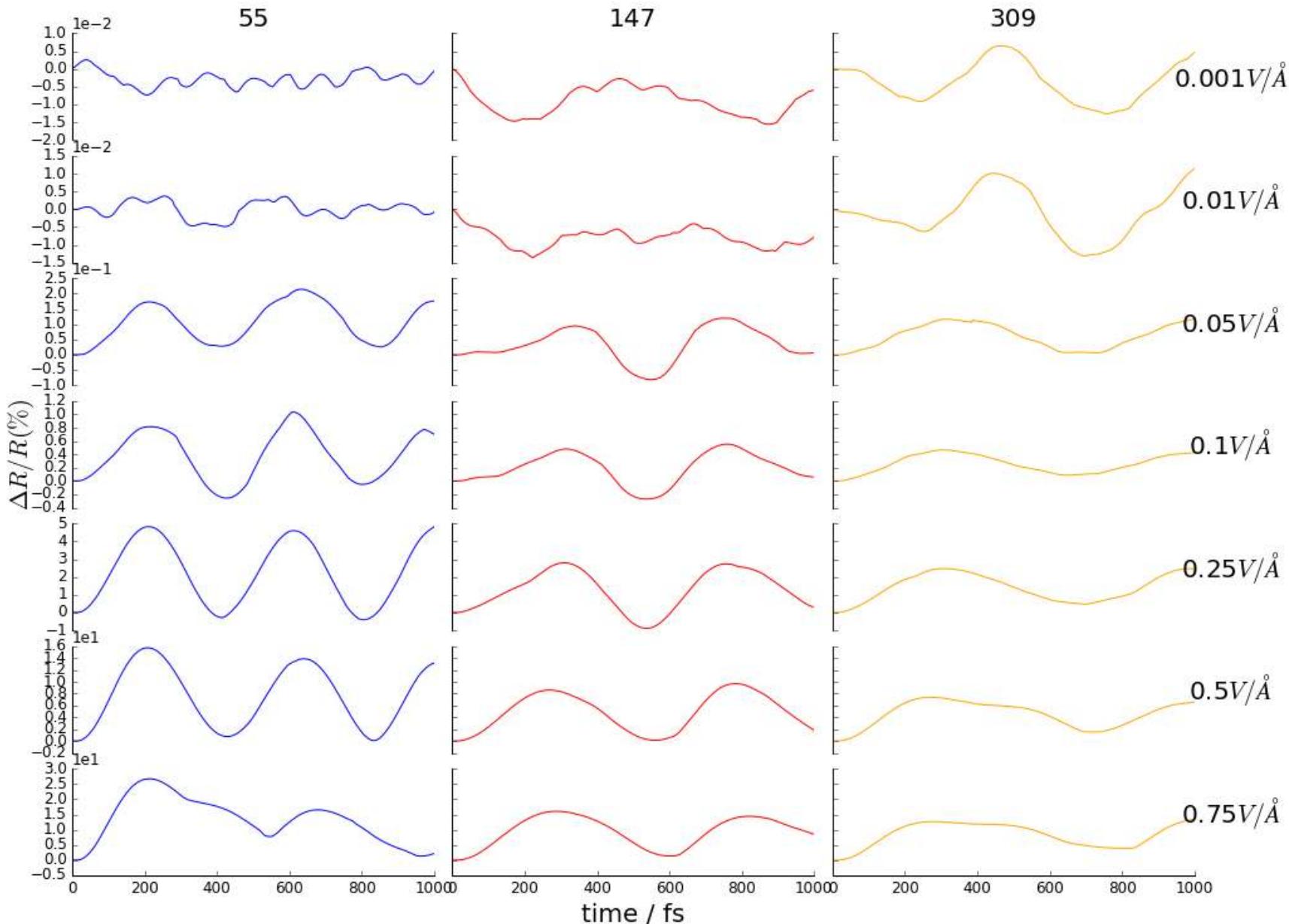
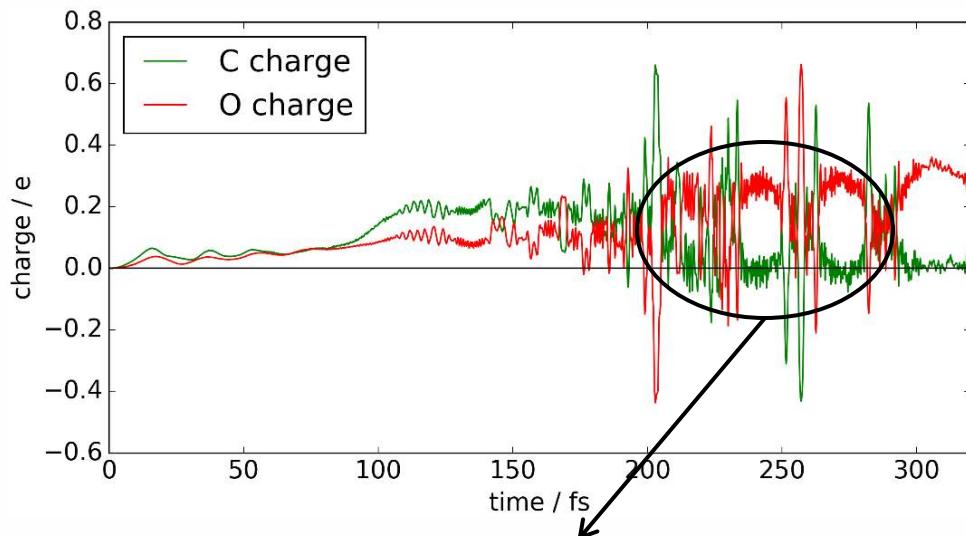
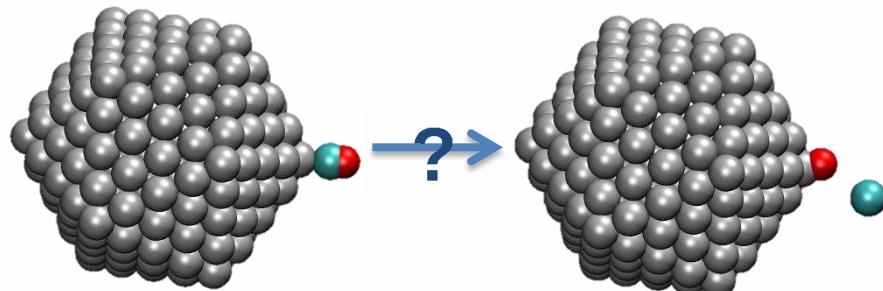
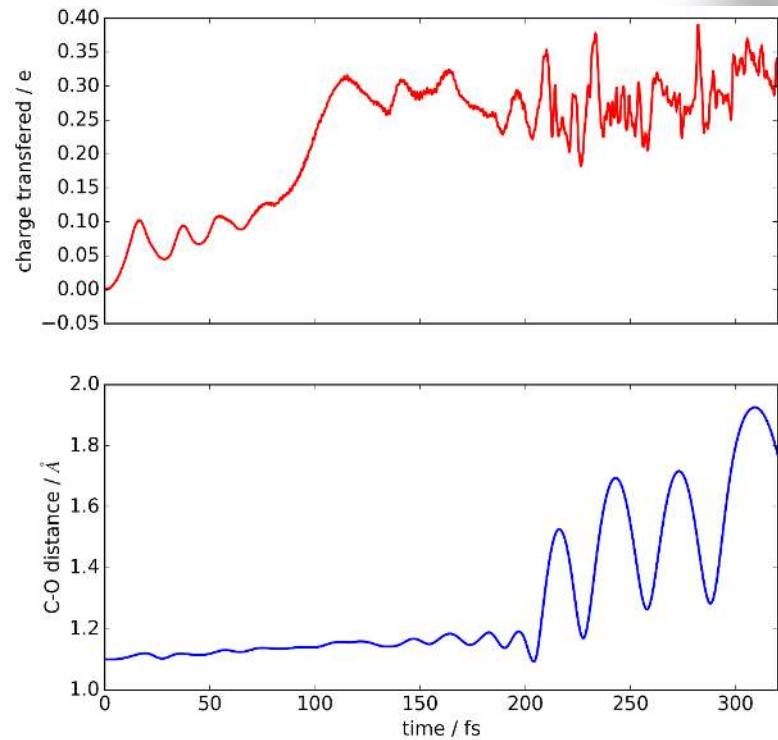


Photo-splitting of CO adsorbed on metal nanoparticles



O holds the negative charge in the antibonding state of CO

NEW application



Work in progress !

Dynamics of charge separation in organic blends

P3HT - PCBM



Chi Yung Yam



Guanhua Chen



Absorption spectra of PCBM and P3HT

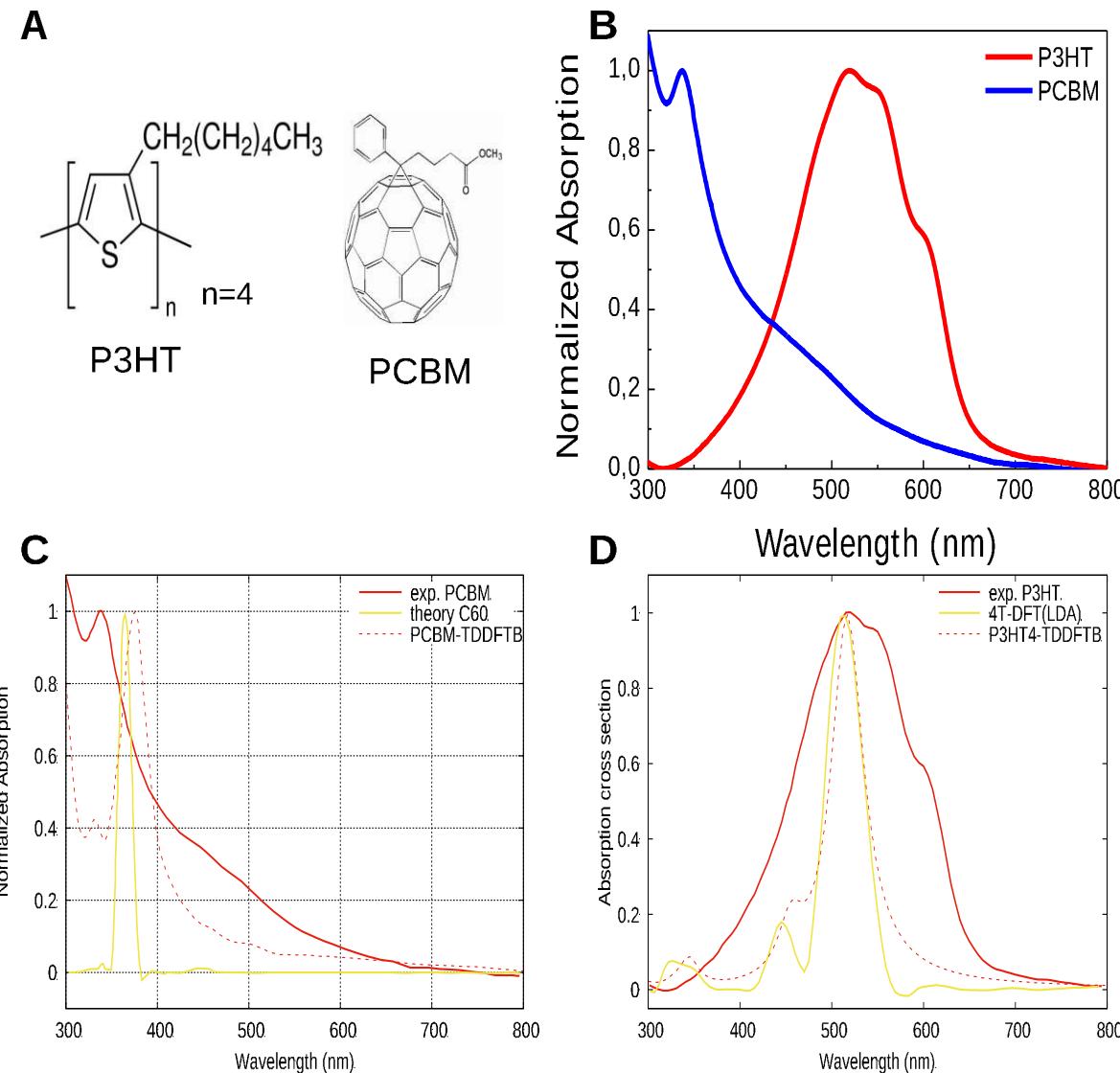
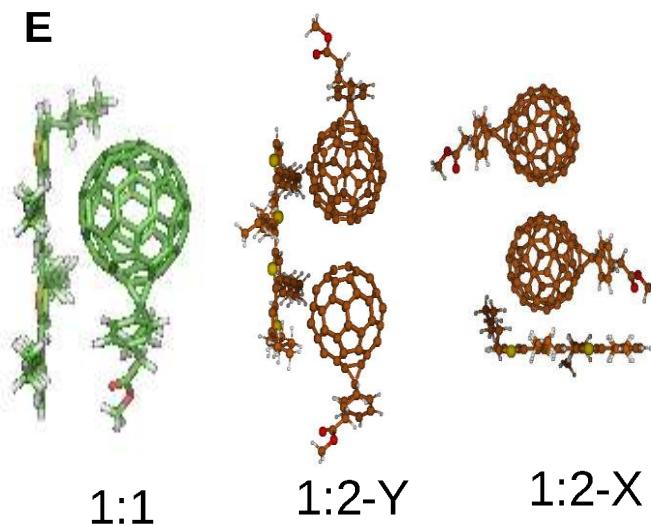
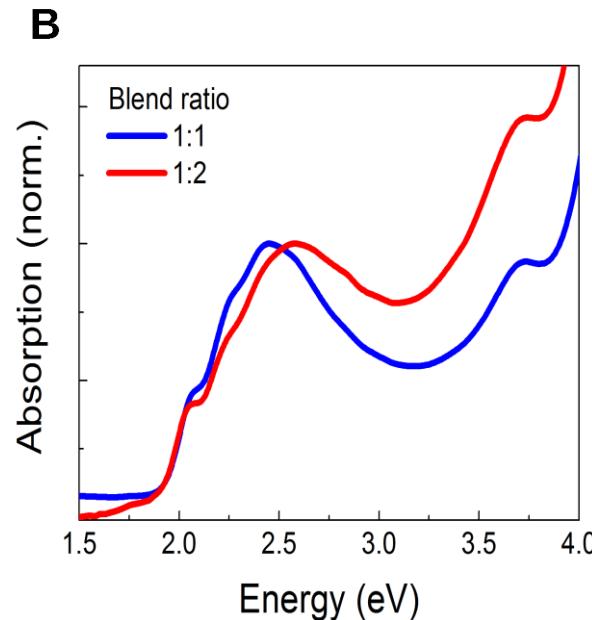
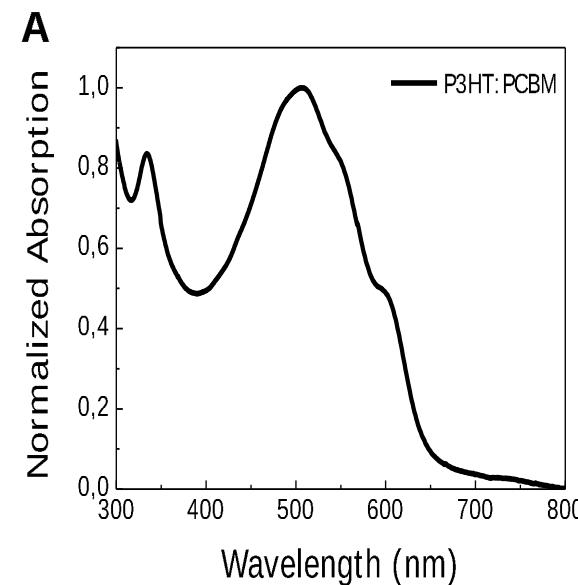


Figure 1 (A) atomic structures of P3HT:PCBM; (B) experiment absorption spectra¹; (C) absorption spectra of PCBM and (D) absorption spectra of P3HT using TD-DFTB

Structures and Absorption Spectra for different aggregation



- 3eV-4eV peak enhancement generated by aggregation of PCBM.

Chr. Lienau
University
Oldenburg
Nanophotonics

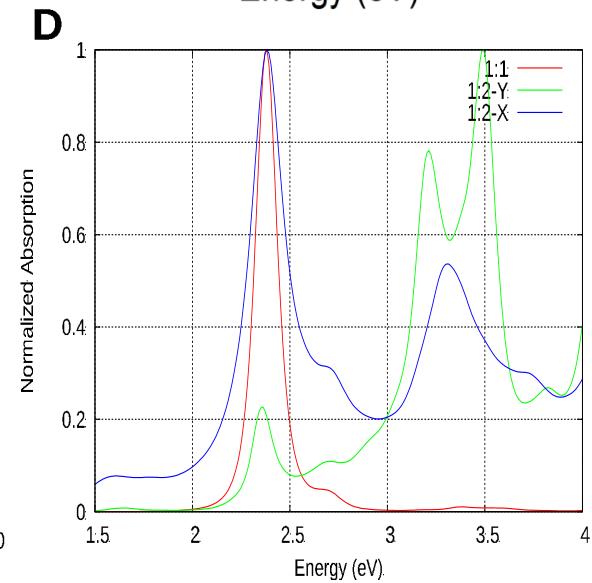
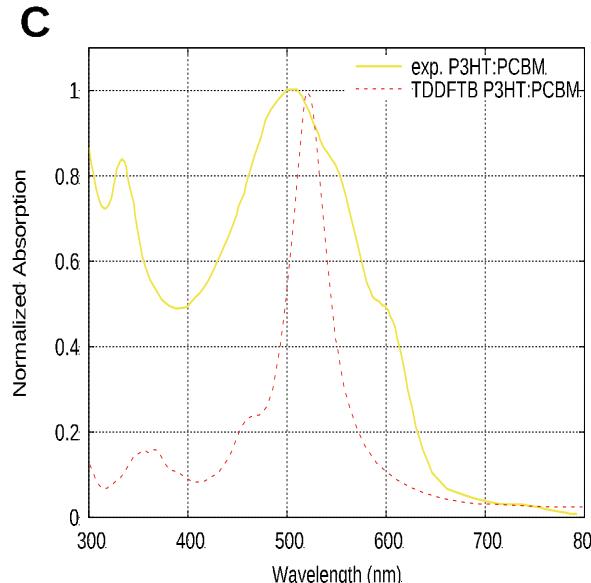
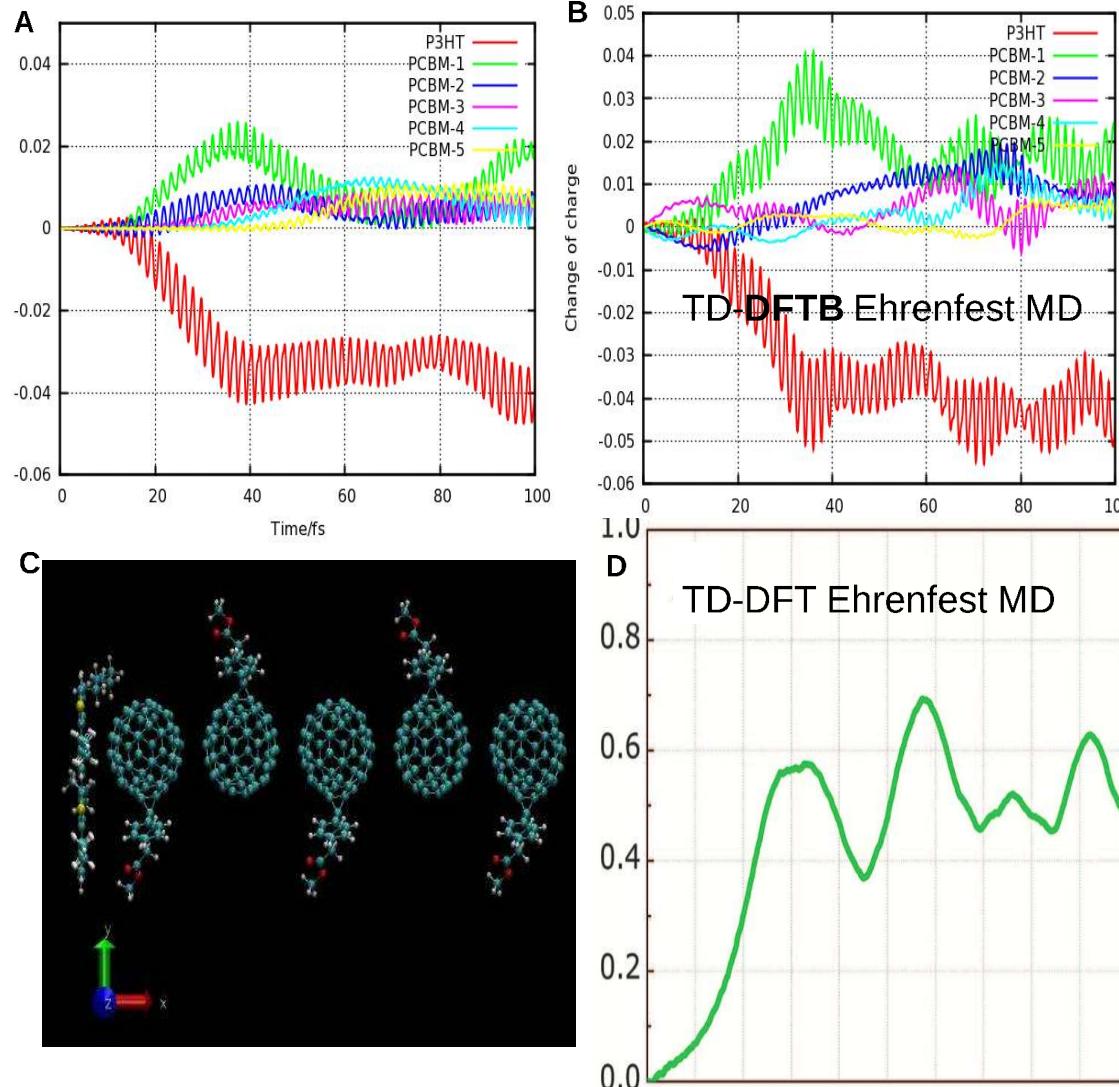


Figure 2 (A) and (B): experiment absorption spectra; (C) and (D): corresponding absorption spectra obtained using TD-DFTB, the atomic structure is shown in (E);

Electron Dynamics with and without Ehrenfest MD

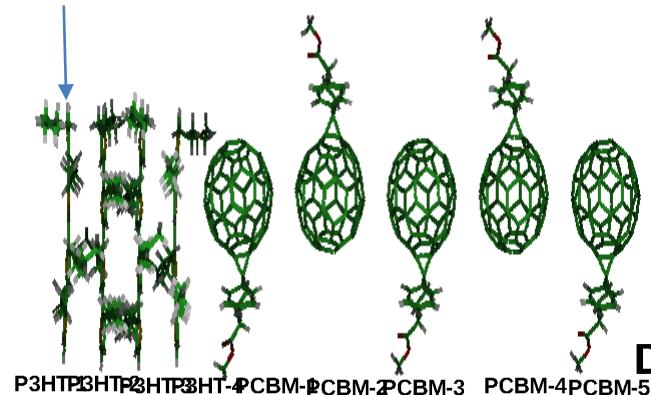


- External field is continuous sine function with frequency corresponding to P3HT absorbance peak;
- External field is applied on P3HT;
- With Ehrenfest, charge transfer process is faster and more charge transfers from P3HT to PCBM;
- The change of charge on P3HT has 20-30fs oscillation which is consistent with TD-DFT Ehrenfest results

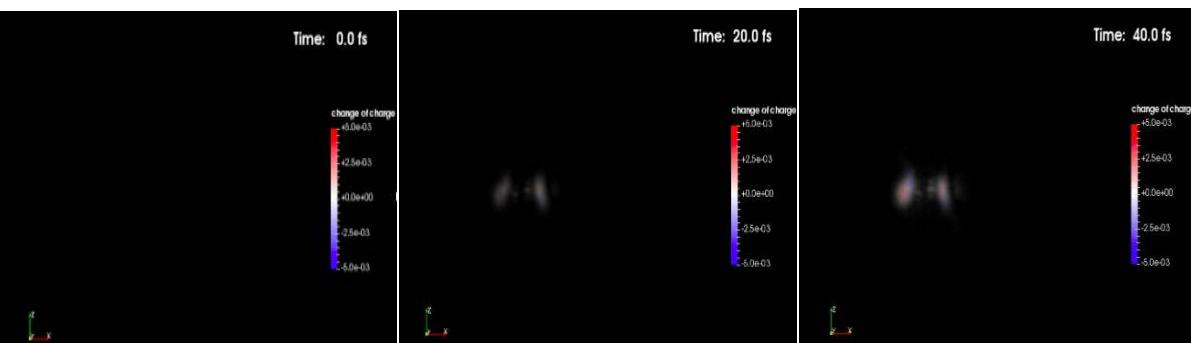
Figure 3. The change of charge on molecular fragments without (A) and with (B) Ehrenfest dynamics. The initial velocity is random assigned. (C) Movie of atomic movement with Ehrenfest dynamics. (D) TD-DFT-Ehrenfest result for system containing one P3HT and one PCBM.¹

Analysis of charge transfer process in multiple layers of P3HT/PCBM

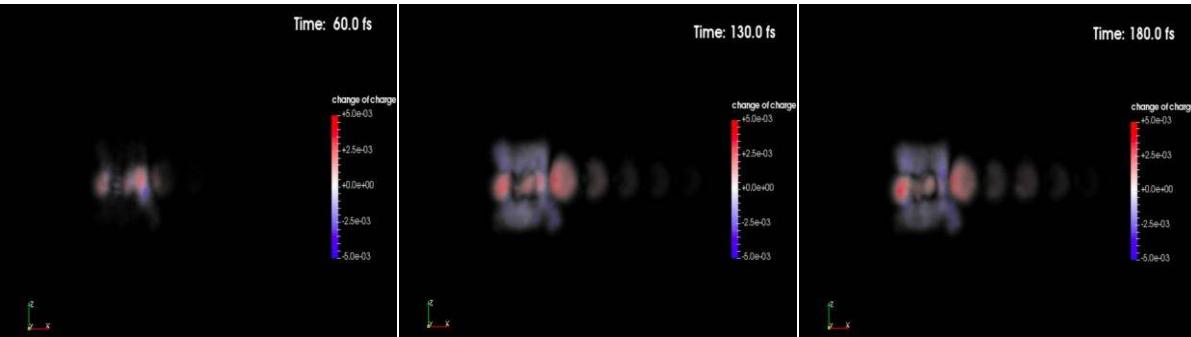
A External Field only applied on P3HT-1



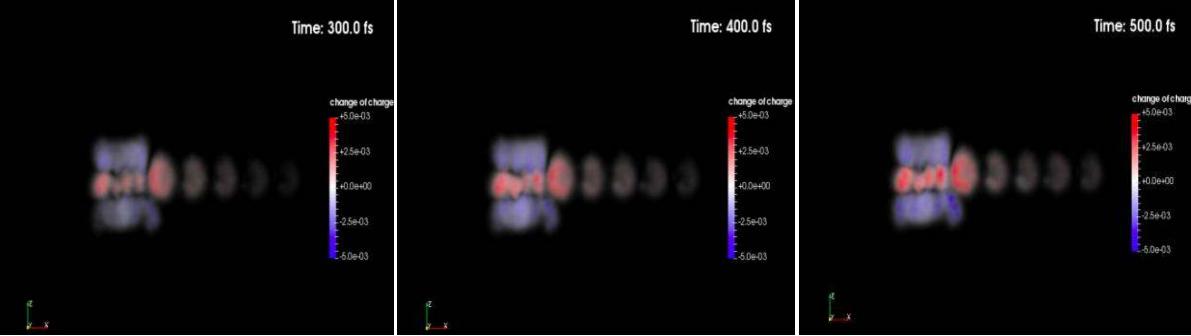
C



D



E



B

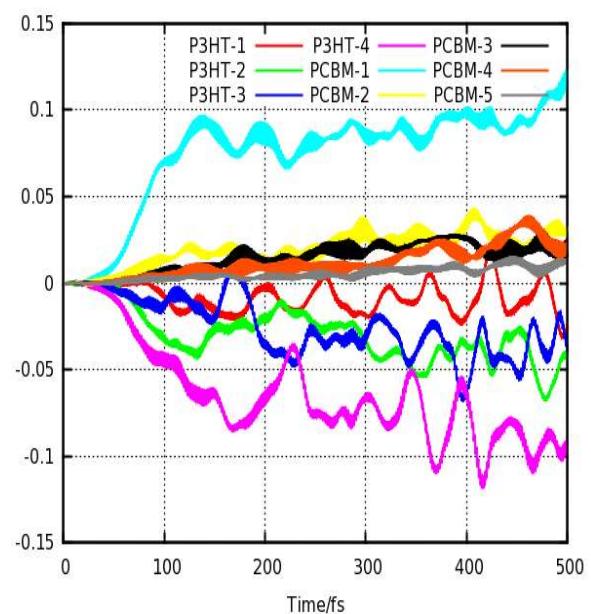
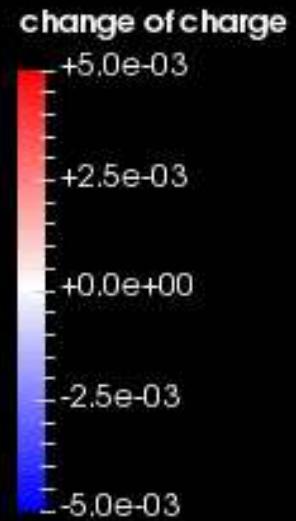


Figure 4 (A) Atomic structure for simulation containing four P3HT and five PCBM aggregates in X direction. (B) The change of charge on each molecular fragments without Ehrenfest; (C,D,E) Snapshots of induced electron density in real space and real time.

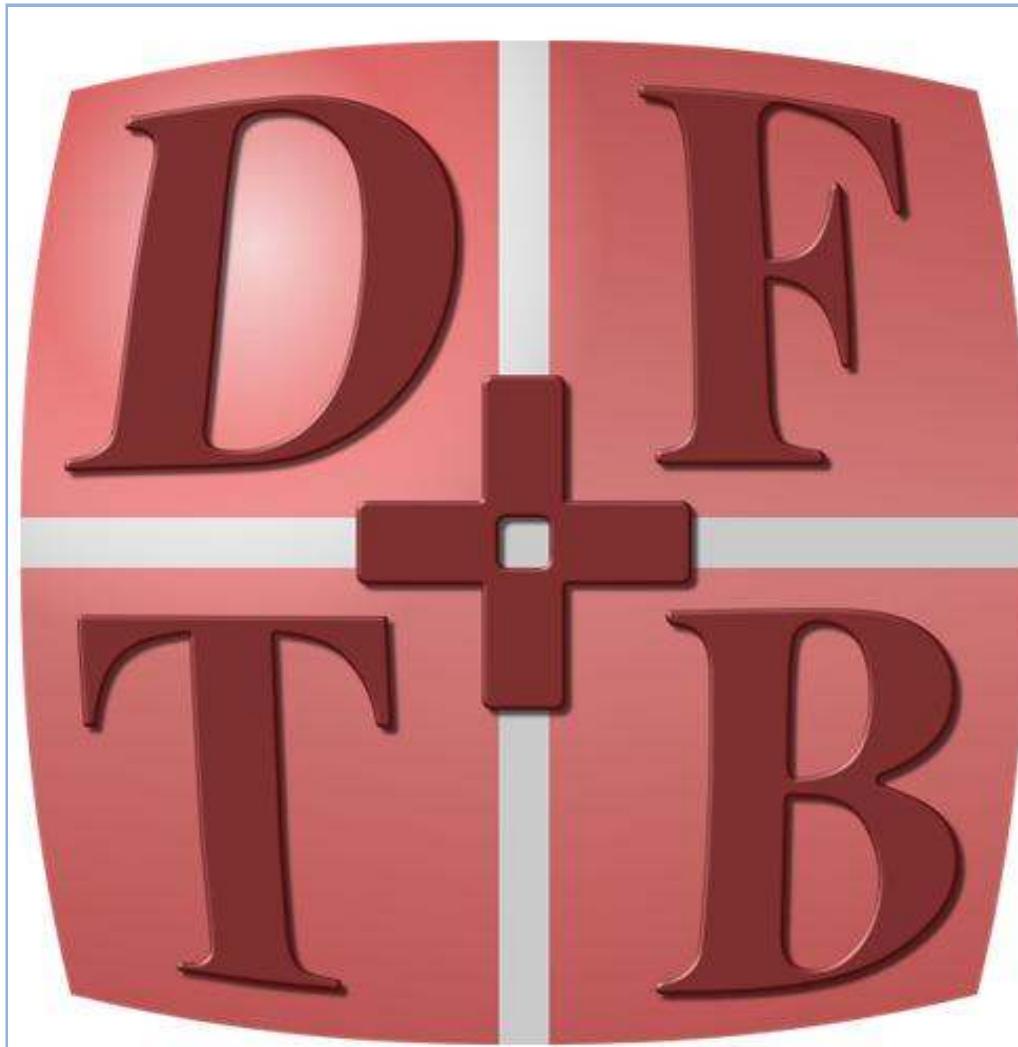
Analysis of charge transfer process in multiple layers of P3HT/PCBM

Time: 0.0 fs

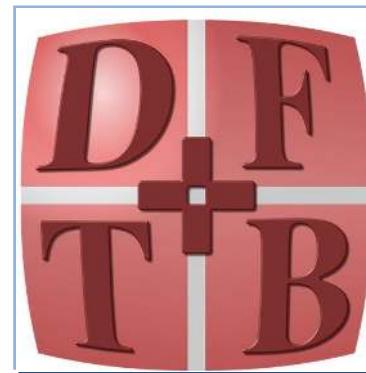
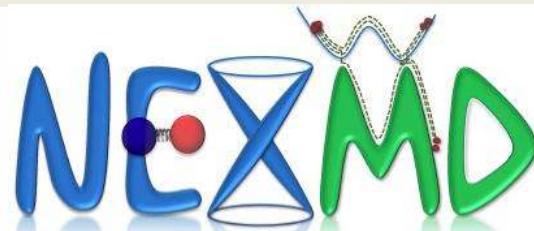


Movie for induced electron density in real space & real time

Summary: DFTB for nanoscale device simulations



DFTB+ connects to world wide software development



Major collaboration partners

Alessandro Pecchia Rome
Alessandro Pecchia Rome



Marcus Elstner Karlsruhe



Qiang Cui Boston



Thomas Niehaus Lyon

Christian Sanchez Cordoba



Oleg Prezhdo USC-LA



Sergei Tretiak LANL



Adrian Roitberg U Florida

Bremen Center for Computational Materials Science

<http://www.bccms.uni-bremen.de>

Acknowledgement – CMS-group



TAB-Building
Technische Akademie Bremen
Am Fallturm 1

Funding agencies: DFG, BMBF, DAAD, AvH, EC,

.....

collaborations around the world

Quantum Mechanical Materials Modelling

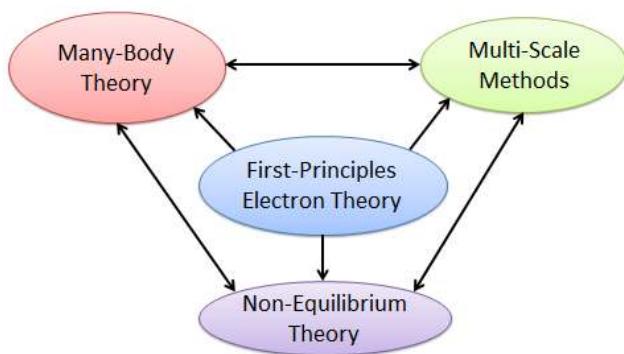
Research Training Group

DFG - RTG 2247

Speaker/Co-Speaker:

T. Frauenheim; T. Wehling

QM³



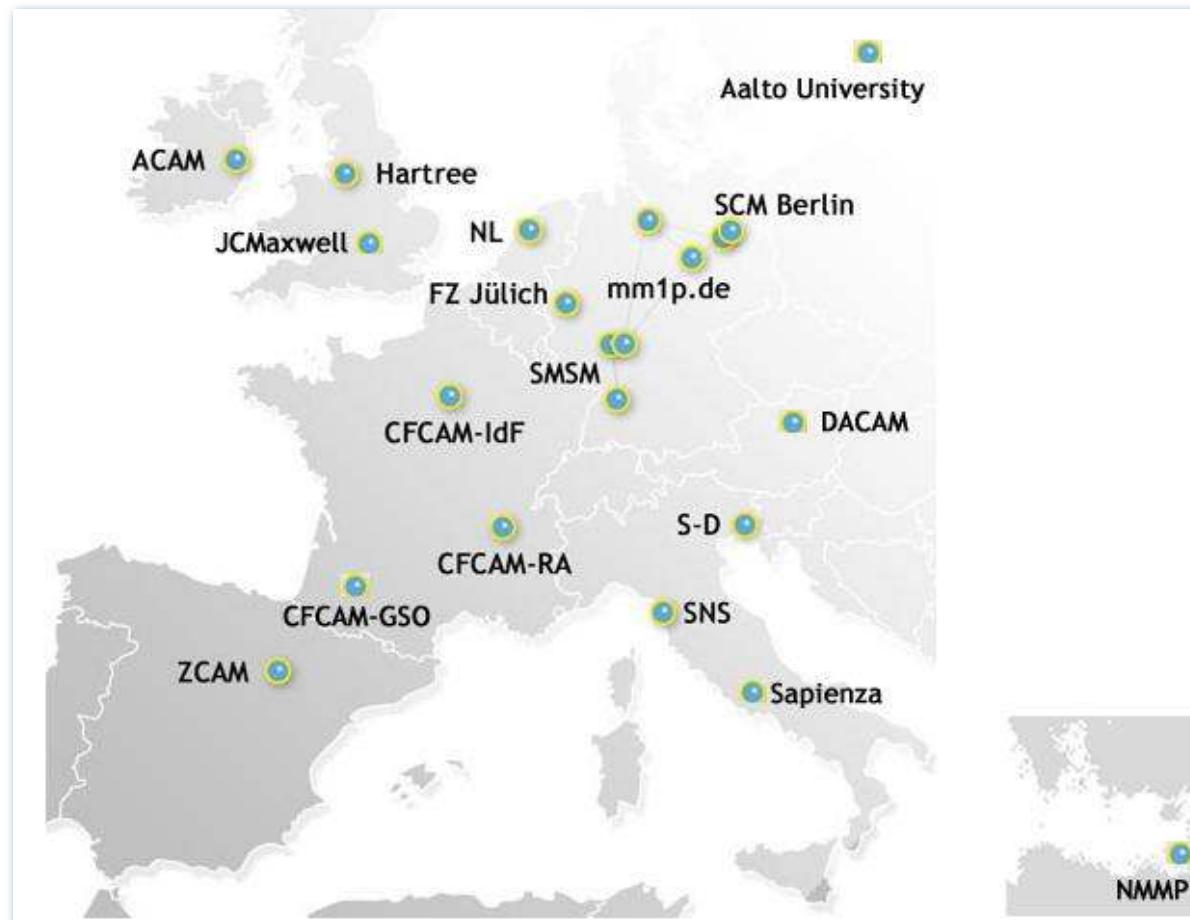


Thank You !

Hope to welcome you
sometime in Bremen



Since 2009 Transformation of CECAM into a multi-nodal structure with CECAM-EPFL as its Headquarter, meanwhile 21 nodes

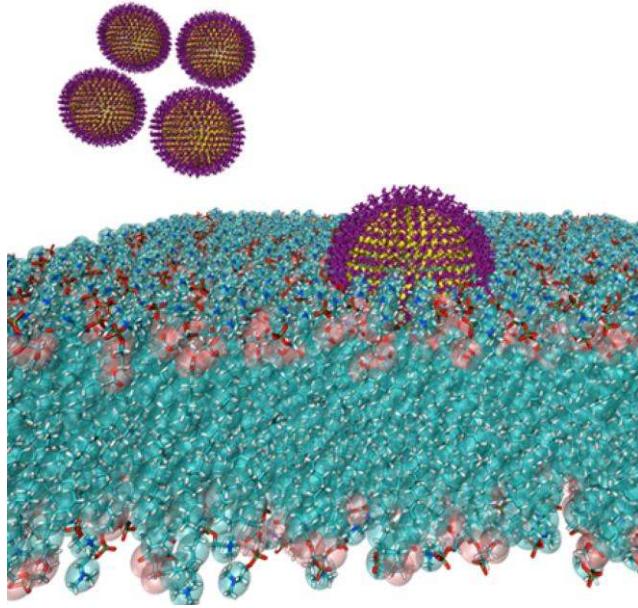


International CECAM Workshop

Tackling Complexity of the Nano/Bio Interface - Computational and Experimental Approaches

Bremen June 12-16th 2017

Applications to nanotoxicity

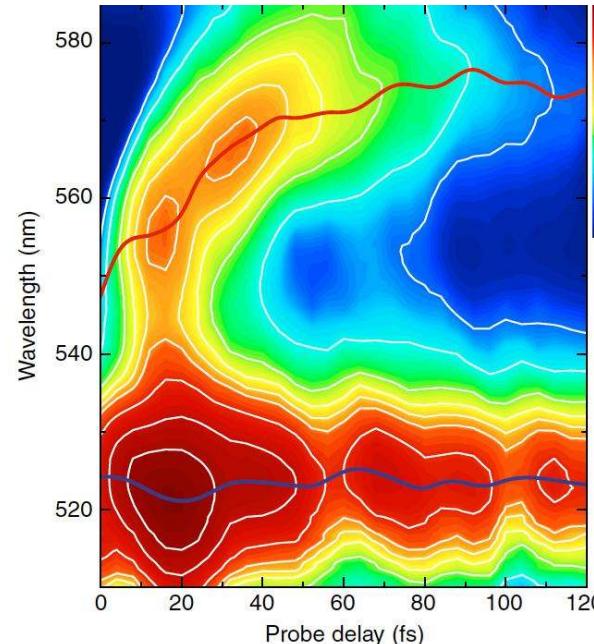


International CECAM Workshop

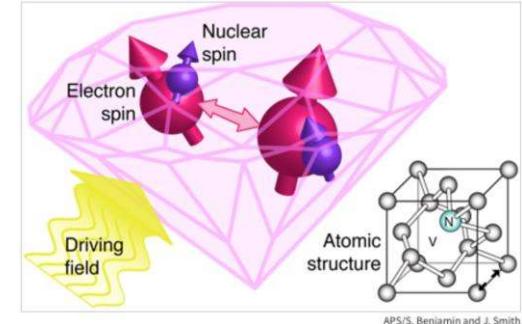
**Charge carrier dynamics in nanostructures:
optoelectronic and photo-stimulated
processes**

Bremen 9-13th October 2017

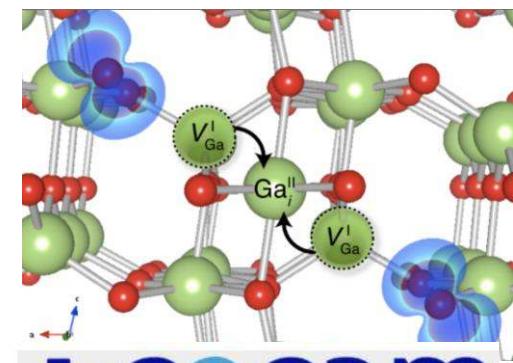
**Applications in photo-catalysis and
photovoltaics**



International CECAM Workshop
Crystal defects for qubits, single photon emitters and nanosensors
Bremen July 9th to 13th 2018



International CECAM Workshop
Reliable and quantitative prediction of defect properties in Ga-based semiconductors
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International CECAM Workshop
Correlated electron physics beyond the Hubbard model
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